

## Excellent Integrated System Limited

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## Dual-Port, Differential, VDSL2 Line Driver Amplifiers

### FEATURES

- **Low Power Consumption:**
  - 21mA/Port (Full Bias Mode)
  - 16.2mA/Port (Mid Bias Mode)
  - 11.2mA/Port (Low Bias Mode)
  - **Low-Power Shutdown Mode**
  - **I<sub>ADJ</sub> Pin for Variable Bias**
- **Low Noise:**
  - 2.7nV/√Hz Voltage Noise
  - 17pA/√Hz Inverting Current Noise
  - 1.2pA/√Hz Noninverting Current Noise
- **Low MTPR Distortion:**
  - 70dB with +20.5dBm G.993.2—Profile 8b
- **–93dBc HD3 (1MHz, 100Ω Differential)**
- **High Output Current: > 416mA (25Ω Load)**
- **Wide Output Swing: 43.2V<sub>PP</sub> (±12V, 100Ω Differential Load)**
- **Wide Bandwidth: 150MHz (G<sub>DIFF</sub> = 10V/V)**
- **PSRR: 50dB at 1MHz for Good Isolation**
- **Wide Power-Supply Range: 10V to 28V**

### APPLICATIONS

- **Ideal For VDSL2 Systems**
- **Backwards-Compatible with ADSL/ADSL2+/ADSL2++ Systems**

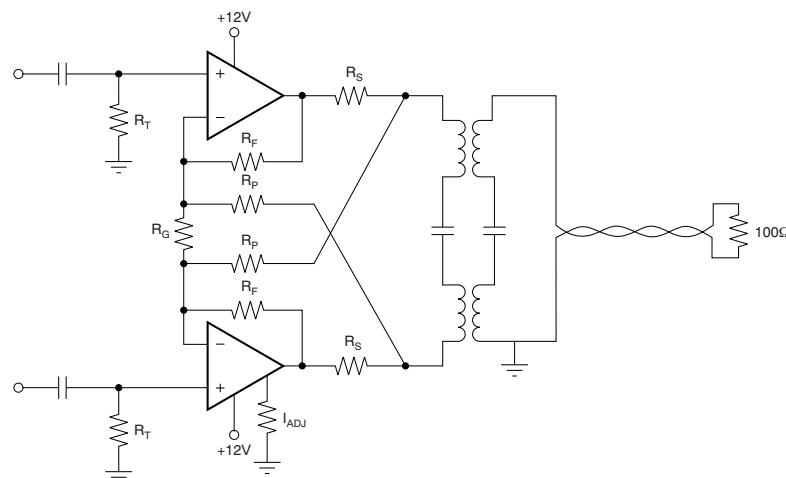
### DESCRIPTION

The THS6214 is a dual-port, current-feedback architecture, differential line driver amplifier system ideal for xDSL systems. The device is targeted for use in VDSL2 (very-high-bit-rate digital subscriber line 2) line driver systems that enable greater than +14.5dBm line power, supporting the G.993.2 VDSL2 17a profile. It is also fast enough to support central-office transmissions of +14.5dBm line power up to 30MHz.

The unique architecture of the THS6214 uses minimal quiescent current while still achieving very high linearity. Differential distortion, under full bias conditions, is –93dBc at 1MHz and reduces to only –73dBc at 10MHz. Fixed multiple bias settings of the amplifiers allow for enhanced power savings for line lengths where the full performance of the amplifier is not required. To allow for even more flexibility and power savings, an adjustable current pin (I<sub>ADJ</sub>) is available to further lower the bias currents.

The wide output swing of 43.2V<sub>PP</sub> (100Ω differential load) with ±12V power supplies, coupled with over 416mA current drive (25Ω load), allows for wide dynamic headroom, keeping distortion minimal.

The THS6214 is available in a QFN-24 or a TSSOP-24 PowerPAD™ package.



**Figure 1. Typical VDSL2 Line Driver Circuit Using One Port of the THS6214**



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### ORDERING INFORMATION<sup>(1)</sup>

| PRODUCT | PACKAGE-LEAD <sup>(2)</sup> | PACKAGE DESIGNATOR | SPECIFIED TEMPERATURE RANGE | PACKAGE MARKING | ORDERING NUMBER | TRANSPORT MEDIA, QUANTITY |
|---------|-----------------------------|--------------------|-----------------------------|-----------------|-----------------|---------------------------|
| THS6214 | QFN-24                      | RHF                | –40°C to +85°C              | 6214            | THS6214IRHFT    | Tape and reel, 250        |
|         |                             |                    |                             |                 | THS6214IRHFR    | Tape and reel, 3000       |
| THS6214 | TSSOP-24                    | PWP                | –40°C to +85°C              | THS6214         | THS6214IPWP     | Tape and reel, 60         |
|         |                             |                    |                             |                 | THS6214IPWPR    | Tape and reel, 2000       |

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).

(2) The PowerPAD™ is electrically isolated from all other pins.

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Over operating free-air temperature range, unless otherwise noted.

|  |  | THS6214                                       | UNIT |
|--|--|---|------|
| Supply voltage, $V_{S-}$ to $V_{S+}$             |  | 28  | V    |
| Input voltage, $V_I$                             |  | $\pm V_S$                                     | V    |
| Differential input voltage, $V_{ID}$             |  | $\pm 2$                                       | V    |
| Output current, $I_O$ : Static dc <sup>(2)</sup> |  | $\pm 500$                                     | mA   |
| Continuous power dissipation                     |  | See <a href="#">Dissipation Ratings</a> Table |      |
| Maximum junction temperature, $T_J$              | Under any condition <sup>(3)</sup>   | +150  | °C   |
|  | Continuous operation, long-term reliability <sup>(4)</sup><br>RHF package only | +130  | °C   |
|  | Continuous operation, long-term reliability <sup>(4)</sup><br>PWP package only | +140  | °C   |
| Storage temperature range, $T_{STG}$             |  | –65 to +150                                   | °C   |
| ESD ratings                                      | Human body model (HBM)   | 2000  | V    |
|  | Charged device model (CDM)   | 500   | V    |
|  | Machine model (MM)   | 100   | V    |

- (1) Stresses above those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated is not implied. Exposure to absolute maximum rated conditions for extended periods may degrade device reliability.
- (2) The THS6214 incorporates a PowerPAD on the underside of the chip. This pad acts as a heatsink and must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature, which could permanently damage the device. See TI Technical Brief [SLMA002](#) for more information about utilizing the PowerPAD thermally-enhanced package. Under high-frequency ac operation (greater than 10kHz), the short-term output current capability is much greater than the continuous dc output current rating. This short-term output current rating is about 8.5 times the dc capability, or about ±850mA.
- (3) The absolute maximum junction temperature under any condition is limited by the constraints of the silicon process.
- (4) The absolute maximum junction temperature for continuous operation is limited by the package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

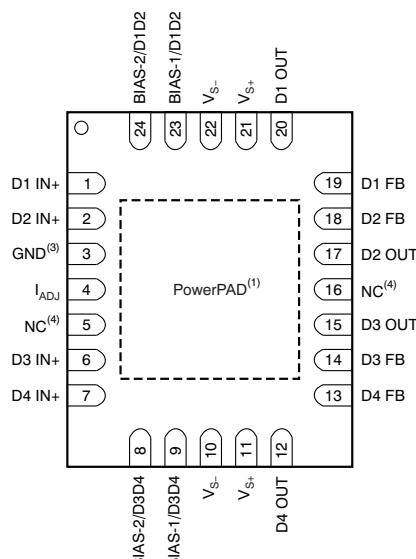
### DISSIPATION RATINGS

| PACKAGE         | $\theta_{JP}$ (°C/W) | $\theta_{JA}$ (°C/W) <sup>(1)</sup> |
|-----------------|----------------------|-------------------------------------|
| QFN-24 (RHF)    | 5                    | 30                                  |
| HTSSOP-24 (PWP) | 7                    | 45                                  |

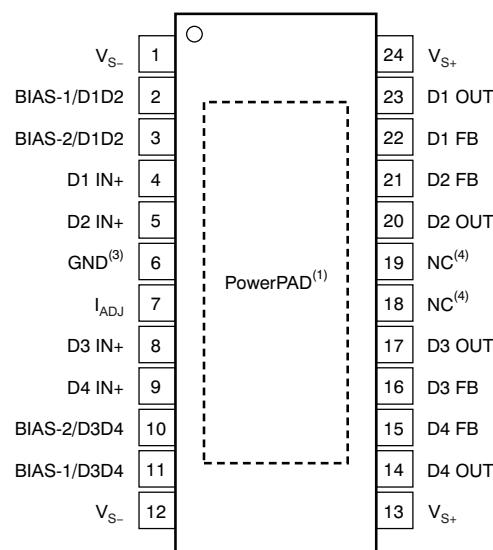
- (1) For high power dissipation applications, soldering the PowerPAD to the PCB is required. Failure to do so may result in reduced reliability and/or lifetime of the device. See TI technical brief [SLMA002](#) for more information about using the PowerPAD thermally enhanced package.

## PIN CONFIGURATIONS<sup>(1)(2)</sup>

**QFN-24  
RHF PACKAGE  
(TOP VIEW)**



**HTSSOP-24  
PWP PACKAGE  
(TOP VIEW)**



- (1) The PowerPAD is electrically isolated from all other pins and can be connected to any potential voltage range from  $V_{S-}$  to  $V_{S+}$ . Typically, the PowerPAD is connected to the GND plane because this plane tends to physically be the largest and is able to dissipate the most amount of heat.
- (2) The THS6214 defaults to the shutdown (disable) state if no signal is present on the bias pins.
- (3) The GND pin range is from  $V_{S-}$  to  $(V_{S+} - 5V)$ .
- (4) NC = no connection.

## ELECTRICAL CHARACTERISTICS: $V_S = \pm 12V$

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +10V/V$  with  $R_L = 100\Omega$  differential load,  $R_{ADJ} = 0\Omega$ , active impedance circuit configuration, and full bias, unless otherwise noted. Each port is independently tested. **Boldface** values are 100% tested at  $+25^\circ C$ .

| PARAMETER                               | CONDITIONS   | THS6214IRHF, IPWP |           |                             | UNIT                | TEST LEVEL <sup>(1)</sup> |
|---|--|-------------------|-----------|-----------------------------|---------------------|---------------------------|
|   |  | MIN               | TYP       | MAX                         |                     |                           |
| <b>AC PERFORMANCE</b>                   |  |                   |           |                             |                     |                           |
| Small-signal bandwidth, $-3dB$          | $G_{DIFF} = +5V/V, R_F = 1.5k\Omega, V_O = 2V_{PP}$              |                   | 160       |                             | MHz                 | C                         |
|   | $G_{DIFF} = +10V/V, R_F = 1.5k\Omega, V_O = 2V_{PP}$             | 120               | 150       |                             | MHz                 | B                         |
|   | Over $-40^\circ C$ to $+85^\circ C$ temperature range            | 100               |           |                             | MHz                 | B                         |
| 0.1dB bandwidth flatness                | $G_{DIFF} = +10V/V, R_F = 1.24k\Omega$                           |                   | 114       |                             | MHz                 | C                         |
| Large-signal bandwidth                  | $G_{DIFF} = +10V/V, R_F = 1.24k\Omega, V_O = 20V_{PP}$           |                   | 120       |                             | MHz                 | C                         |
| Slew rate (10% to 90% level)            | $G_{DIFF} = +10V/V, V_O = 20V$ step, differential                | 3200              | 3800      |                             | V/ $\mu$ s          | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             | 3000              |           |                             | V/ $\mu$ s          | B                         |
| Rise and fall time                      | $G_{DIFF} = +10V/V, V_O = 2V_{PP}$                               |                   | 5         |                             | ns                  | C                         |
| Harmonic distortion                     | $G_{DIFF} = +10V/V, V_O = 2V_{PP}, R_L = 100\Omega$ differential |                   |           |                             |                     | C                         |
| 2nd harmonic                            | Full bias, $f = 1MHz$  |                   | -100      | -95                         | dBc                 | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | -90                         | dBc                 | B                         |
|   | Low bias, $f = 1MHz$   |                   | -96       |                             | dBc                 | C                         |
| 3rd harmonic                            | Full bias, $f = 1MHz$  |                   | -89       | -85                         | dBc                 | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | -80                         | dBc                 | B                         |
|   | Low bias, $f = 1MHz$   |                   | -85       |                             | dBc                 | C                         |
| 2nd harmonic                            | Full bias, $f = 10MHz$   |                   | -75       | -70                         | dBc                 | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | -65                         | dBc                 | B                         |
|   | Low bias, $f = 10MHz$  |                   | -72       |                             | dBc                 | C                         |
| 3rd harmonic                            | Full bias, $f = 10MHz$   |                   | -73       | -65                         | dBc                 | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | -53                         | dBc                 | B                         |
|   | Low bias, $f = 10MHz$  |                   | -58       |                             | dBc                 | C                         |
| Differential input voltage noise        | $f = 1MHz$ , input-referred                                      |                   | 2.7       | 3.2                         | nV/ $\sqrt{Hz}$     | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | 3.5                         | nV/ $\sqrt{Hz}$     | B                         |
| Differential noninverting current noise | $f = 1MHz$   |                   | 1.2       | 1.4                         | pA/ $\sqrt{Hz}$     | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           |                             |                     |                           |
| Differential inverting current noise    | $f = 1MHz$   |                   | 17        | 20                          | pA/ $\sqrt{Hz}$     | B                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | 24                          | pA/ $\sqrt{Hz}$     | B                         |
| <b>DC PERFORMANCE</b>                   |  |                   |           |                             |                     |                           |
| Open-loop transimpedance gain           | $R_L = 100\Omega$  | 330               | 700       |                             | k $\Omega$          | A                         |
|   |  | 300               |           |                             | k $\Omega$          | B                         |
| Input offset voltage                    |  |                   | $\pm 15$  | <b><math>\pm 50</math></b>  | mV                  | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 60$                    | mV                  | B                         |
| Input offset voltage drift              | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 155$                   | $\mu$ V/ $^\circ C$ | B                         |
| Input offset voltage matching           | Channels 1 to 2 and 3 to 4 only                                  |                   | $\pm 0.5$ | <b><math>\pm 5</math></b>   | mV                  | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 7$                     | mV                  | B                         |
| Noninverting input bias current         |  |                   | $\pm 1$   | <b><math>\pm 3.5</math></b> | $\mu$ A             | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 5.5$                   | $\mu$ A             | B                         |
| Noninverting input bias current drift   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | <b><math>\pm 30</math></b>  | nA/ $^\circ C$      | B                         |
| Inverting input bias current            |  |                   | $\pm 8$   | <b><math>\pm 45</math></b>  | $\mu$ A             | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 55$                    | $\mu$ A             | B                         |
| Inverting input bias current drift      | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 154$                   | nA/ $^\circ C$      | B                         |
| Inverting input bias current matching   |  |                   | $\pm 8$   | <b><math>\pm 30</math></b>  | $\mu$ A             | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                             |                   |           | $\pm 40$                    | $\mu$ A             | B                         |

(1) Test levels: (A) 100% tested at  $+25^\circ C$ . Over-temperature limits set by characterization and simulation. (B) Limits set by characterization and simulation. (C) Typical value only for information.

## ELECTRICAL CHARACTERISTICS: $V_S = \pm 12V$ (continued)

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +10V/V$  with  $R_L = 100\Omega$  differential load,  $R_{ADJ} = 0\Omega$ , active impedance circuit configuration, and full bias, unless otherwise noted. Each port is independently tested. **Boldface** values are 100% tested at  $+25^\circ C$ .

| PARAMETER                                   | CONDITIONS  | THS6214IRHF, IPWP            |                   |                            | UNIT                      | TEST LEVEL <sup>(1)</sup> |
|---|---|------------------------------|-------------------|----------------------------|---------------------------|---------------------------|
|   |   | MIN                          | TYP               | MAX                        |                           |                           |
| <b>INPUT CHARACTERISTICS</b>                |   |                              |                   |                            |                           |                           |
| Common-mode input range                     | Each input  | <b><math>\pm 9</math></b>    | $\pm 9.5$         |                            | V                         | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | $\pm 8.6$                    |                   |                            | V                         | B                         |
| Common-mode rejection ratio                 | Each input  | <b>53</b>                    | 65                |                            | dB                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 49                           |                   |                            | dB                        | B                         |
| Noninverting input resistance               |   |                              | 500 $\parallel$ 2 |                            | k $\Omega$ $\parallel$ pF | C                         |
| Inverting input resistance                  |   |                              | 50                |                            | $\Omega$                  | C                         |
| <b>OUTPUT CHARACTERISTICS<sup>(2)</sup></b> |   |                              |                   |                            |                           |                           |
| Output voltage swing                        | $R_L = 100\Omega$ , each output                     |                              | $\pm 10.9$        |                            | V                         | C                         |
|   | $R_L = 50\Omega$ , each output                      | <b><math>\pm 10.6</math></b> | $\pm 10.8$        |                            | V                         | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | $\pm 10.4$                   |                   |                            | V                         | B                         |
|   | $R_L = 25\Omega$ , each output                      | <b><math>\pm 10.2</math></b> | $\pm 10.4$        |                            | V                         | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | $\pm 10$                     |                   |                            | V                         | B                         |
| Output current (sourcing and sinking)       | $R_L = 25\Omega$ , based on $V_{OUT}$ tests         | <b><math>\pm 408</math></b>  | $\pm 416$         |                            | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | $\pm 400$                    |                   |                            | mA                        | B                         |
| Short-circuit output current                |   |                              | 1                 |                            | A                         | C                         |
| Output impedance                            | $f = 1MHz$ , differential                           |                              | 0.2               |                            | $\Omega$                  | C                         |
| Crosstalk                                   | $f = 1MHz$ , $V_{OUT} = 2V_{PP}$ , Port 1 to Port 2 |                              | -90               |                            | dB                        | C                         |
| <b>POWER SUPPLY</b>                         |   |                              |                   |                            |                           |                           |
| Operating voltage                           |   | $\pm 5$                      | $\pm 12$          | <b><math>\pm 14</math></b> | V                         | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | $\pm 5$                      |                   | $\pm 14$                   | V                         | C                         |
| $I_{S+}$ Quiescent current                  | Per port, full bias (Bias-1 = 0, Bias-2 = 0)        | <b>19.5</b>                  | 21                | <b>22.5</b>                | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 17                           |                   | 24                         | mA                        | B                         |
|   | Per port, mid bias (Bias-1 = 1, Bias-2 = 0)         | <b>15</b>                    | 16.2              | <b>17.4</b>                | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 12.8                         |                   | 18.6                       | mA                        | B                         |
|   | Per port, low bias (Bias-1 = 0, Bias-2 = 1)         | <b>10</b>                    | 11.2              | <b>12.4</b>                | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 8.1                          |                   | 13.2                       | mA                        | B                         |
|   | Per port, bias off (Bias-1 = 1, Bias-2 = 1)         |                              | 0.4               | <b>0.8</b>                 | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                |                              |                   | 1                          | mA                        | B                         |
| $I_{S-}$ Quiescent current                  | Per port, full bias (Bias-1 = 0, Bias-2 = 0)        | <b>18.5</b>                  | 20                | <b>21.5</b>                | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 16                           |                   | 23                         | mA                        | B                         |
|   | Per port, mid bias (Bias-1 = 1, Bias-2 = 0)         | <b>14</b>                    | 15.2              | <b>16.4</b>                | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 11.8                         |                   | 17.6                       | mA                        | B                         |
|   | Per port, low bias (Bias-1 = 0, Bias-2 = 1)         | <b>9</b>                     | 10.2              | <b>11.6</b>                | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 7.1                          |                   | 11.4                       | mA                        | B                         |
|   | Per port, bias off (Bias-1 = 1, Bias-2 = 1)         |                              | 0.1               | <b>0.3</b>                 | mA                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                |                              |                   | 0.8                        | mA                        | B                         |
| Current through GND pin                     | Per port, full bias (Bias-1 = 0, Bias-2 = 0)        |                              | 1                 |                            | mA                        | C                         |
| Power-supply rejection ratio (+PSRR)        | Differential  | <b>54</b>                    | 66                |                            | dB                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 52                           |                   |                            | dB                        | B                         |
| Power-supply rejection ratio (-PSRR)        | Differential  | <b>52</b>                    | 65                |                            | dB                        | A                         |
|   | $T_A = -40^\circ C$ to $+85^\circ C$                | 50                           |                   |                            | dB                        | B                         |

(2) Test circuit is shown in [Figure 1](#).

**ELECTRICAL CHARACTERISTICS:  $V_S = \pm 12V$  (continued)**

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +10V/V$  with  $R_L = 100\Omega$  differential load,  $R_{ADJ} = 0\Omega$ , active impedance circuit configuration, and full bias, unless otherwise noted. Each port is independently tested. **Boldface** values are 100% tested at  $+25^\circ C$ .

| PARAMETER                         | CONDITIONS   | THS6214IRHF, IPWP |         |           | UNIT            | TEST LEVEL <sup>(1)</sup> |
|-----------------------------------|--|-------------------|---------|-----------|-----------------|---------------------------|
|                                   |  | MIN               | TYP     | MAX       |                 |                           |
| <b>LOGIC</b>                      |  |                   |         |           |                 |                           |
| Bias control pin logic threshold  | Logic 1, with respect to GND <sup>(3)</sup> , $T_A = -40^\circ C$ to $+85^\circ C$<br>Logic 0, with respect to GND <sup>(3)</sup> , $T_A = -40^\circ C$ to $+85^\circ C$ | 1.9               |         | 0.8       | V               | B                         |
| Bias pin quiescent current        | Bias-1, Bias-2 = 0.5V (logic 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Bias-1, Bias-2 = 3.3V (logic 1)<br>$T_A = -40^\circ C$ to $+85^\circ C$                       |                   | 20      | <b>30</b> | $\mu A$         | A                         |
|                                   |  |                   |         | 35        | $\mu A$         | B                         |
|                                   |  |                   | 0.3     | <b>1</b>  | $\mu A$         | A                         |
|                                   |  |                   |         | 1.2       | $\mu A$         | B                         |
| Turn-on time delay ( $t_{ON}$ )   | Time for $I_S$ to reach 50% of final value   |                   | 1       |           | $\mu s$         | C                         |
| Turn-off time delay ( $t_{OFF}$ ) | Time for $I_S$ to reach 50% of final value   |                   | 1       |           | $\mu s$         | C                         |
| Bias pin input impedance          |  |                   | 50      |           | $k\Omega$       | C                         |
| Amplifier output impedance        | Off bias (Bias-1 = 1, Bias-2 = 1)  |                   | 10    5 |           | $k\Omega    pF$ | C                         |

(3) The GND pin usable range is from  $V_{S-}$  to  $(V_{S+} - 5V)$ .

## ELECTRICAL CHARACTERISTICS: $V_S = \pm 6V$

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +5V/V$  with  $R_L = 100\Omega$  differential load,  $R_{ADJ} = 0\Omega$ , active impedance circuit configuration, and full bias, unless otherwise noted. Each port is independently tested.

| PARAMETER  | CONDITIONS  | THS6214IRHF, IPWP |           |           | UNIT             | TEST LEVEL <sup>(1)</sup> |
|--|---|-------------------|-----------|-----------|------------------|---------------------------|
|  |   | MIN               | TYP       | MAX       |                  |                           |
| <b>AC PERFORMANCE</b>                            |   |                   |           |           |                  |                           |
| Small-signal bandwidth, -3dB ( $V_O = 2V_{PP}$ ) | $G_{DIFF} = +5V/V$ , $R_F = 1.5k\Omega$ , $V_O = 2V_{PP}$<br>$G_{DIFF} = +10V/V$ , $R_F = 1.5k\Omega$ , $V_O = 2V_{PP}$<br>$T_A = -40^\circ C$ to $+85^\circ C$ | 110               | 140       | 95        | MHz              | C                         |
| 0.1dB bandwidth flatness                         | $G_{DIFF} = +10V/V$ , $R_F = 1.24k\Omega$   |                   | 100       |           | MHz              | B                         |
| Large-signal bandwidth                           | $G_{DIFF} = +5V/V$ , $R_F = 1.24k\Omega$ , $V_O = 20V_{PP}$   |                   | 120       |           | MHz              | C                         |
| Slew rate (10% to 90% level)                     | $G_{DIFF} = +10V/V$ , $V_O = 20V$ step, differential<br>Over $-40^\circ C$ to $+85^\circ C$ temperature range   | 1200              | 1600      |           | V/ $\mu$ s       | B                         |
| Rise and fall time                               | $G_{DIFF} = +10V/V$ , $V_O = 2V_{PP}$   | 1000              | 5         |           | V/ $\mu$ s       | B                         |
| Harmonic distortion                              | $G_{DIFF} = +10V/V$ , $V_O = 2V_{PP}$ , $f = 1MHz$ , $R_L = 100\Omega$ differential   |                   |           |           |                  | C                         |
| 2nd harmonic                                     | Full bias<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Low bias   |                   | -98       | -92       | dBc              | B                         |
| 3rd harmonic                                     | Full bias<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Low bias   |                   | -93       | -84       | dBc              | B                         |
| 2nd harmonic                                     | Full bias<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Low bias   |                   | -89       | -75       | dBc              | C                         |
| 3rd harmonic                                     | Full bias<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Low bias   |                   | -80       | -68       | dBc              | B                         |
| Differential input voltage noise                 | Low bias<br>$f = 1MHz$ , input-referred<br>$T_A = -40^\circ C$ to $+85^\circ C$   |                   | -74       | -60       | dBc              | C                         |
| Differential noninverting current noise          | $f = 1MHz$<br>$T_A = -40^\circ C$ to $+85^\circ C$  |                   | -66       | -54       | dBc              | B                         |
| Differential inverting current noise             | $f = 1MHz$<br>$T_A = -40^\circ C$ to $+85^\circ C$  |                   | -55       | -55       | dBc              | C                         |
|  |   |                   | 2.5       | 3.0       | nV/ $\sqrt{Hz}$  | B                         |
|  |   |                   |           | 3.3       | nV/ $\sqrt{Hz}$  | B                         |
|  |   |                   | 1.2       | 1.4       | pA/ $\sqrt{Hz}$  | B                         |
|  |   |                   |           | 1.6       | pA/ $\sqrt{Hz}$  | B                         |
|  |   |                   | 17        | 20        | pA/ $\sqrt{Hz}$  | B                         |
|  |   |                   |           | 24        | pA/ $\sqrt{Hz}$  | B                         |
| <b>DC PERFORMANCE</b>                            |   |                   |           |           |                  |                           |
| Open-loop transimpedance gain                    | $R_L = 100\Omega$<br>$T_A = -40^\circ C$ to $+85^\circ C$   | 330               | 650       |           | k $\Omega$       | A                         |
| Input offset voltage                             |   | 300               | $\pm 10$  | $\pm 45$  | mV               | B                         |
| Input offset voltage drift                       | $T_A = -40^\circ C$ to $+85^\circ C$  |                   |           | $\pm 55$  | mV               | B                         |
| Input offset voltage matching                    | $T_A = -40^\circ C$ to $+85^\circ C$<br>Channels 1 to 2 and 3 to 4 only   |                   | $\pm 0.5$ | $\pm 155$ | $\mu V/^\circ C$ | B                         |
| Noninverting input bias current                  | $T_A = -40^\circ C$ to $+85^\circ C$  |                   | $\pm 1$   | $\pm 5$   | $\mu V/^\circ C$ | B                         |
| Noninverting input bias current drift            | $T_A = -40^\circ C$ to $+85^\circ C$  |                   |           | $\pm 7$   | $\mu V/^\circ C$ | B                         |
| Inverting input bias current                     | $T_A = -40^\circ C$ to $+85^\circ C$  |                   |           | $\pm 1$   | $\mu A$          | A                         |
| Inverting input bias current drift               | $T_A = -40^\circ C$ to $+85^\circ C$  |                   |           | $\pm 3.5$ | $\mu A$          | A                         |
| Inverting input bias current matching            | $T_A = -40^\circ C$ to $+85^\circ C$  |                   |           | $\pm 5.5$ | $\mu A$          | B                         |
|  |   |                   |           | $\pm 30$  | nA/ $^\circ C$   | B                         |
|  |   |                   |           | $\pm 8$   | $\mu A$          | A                         |
|  |   |                   |           | $\pm 45$  | $\mu A$          | A                         |
|  |   |                   |           | $\pm 7$   | $\mu A$          | B                         |
|  |   |                   |           | $\pm 135$ | nA/ $^\circ C$   | B                         |
|  |   |                   |           | $\pm 8$   | $\mu A$          | A                         |
|  |   |                   |           | $\pm 30$  | $\mu A$          | B                         |
|  |   |                   |           | $\pm 40$  | $\mu A$          | B                         |

(1) Test levels: (A) 100% tested at  $+25^\circ C$ . Over-temperature limits set by characterization and simulation. (B) Limits set by characterization and simulation. (C) Typical value only for information.

## ELECTRICAL CHARACTERISTICS: $V_S = \pm 6V$ (continued)

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +5V/V$  with  $R_L = 100\Omega$  differential load,  $R_{ADJ} = 0\Omega$ , active impedance circuit configuration, and full bias, unless otherwise noted. Each port is independently tested.

| PARAMETER                                   | CONDITIONS   | THS6214IRHF, IPWP   |  |  | UNIT   | TEST LEVEL <sup>(1)</sup>  |
|---|--|---|--|--|--|--|
|   |  | MIN   | TYP  | MAX  |  |  |
| <b>INPUT CHARACTERISTICS</b>                |  |   |  |  |  |  |
| Common-mode input range                     | Each input<br>$T_A = -40^\circ C$ to $+85^\circ C$   | <b><math>\pm 2.9</math></b><br>$\pm 2.7$  | $\pm 3.0$  |  | V<br>V   | A<br>B   |
| Common-mode rejection ratio                 | Each input<br>$T_A = -40^\circ C$ to $+85^\circ C$   | <b>51</b><br>47   | 62   |  | dB<br>dB   | A<br>B   |
| Noninverting input resistance               |  |   |  | 500    2   | k $\Omega$    pF   | C  |
| Inverting input resistance                  |  |   |  | 55   | $\Omega$   | C  |
| <b>OUTPUT CHARACTERISTICS<sup>(2)</sup></b> |  |   |  |  |  |  |
| Output voltage swing                        | $R_L = 100\Omega$ , each output<br>$R_L = 50\Omega$ , each output<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>$R_L = 25\Omega$ , each output<br>$T_A = -40^\circ C$ to $+85^\circ C$  | <b><math>\pm 4.75</math></b><br>$\pm 4.6$   | $\pm 4.9$<br>$\pm 4.9$   |  | V<br>V<br>V<br>V<br>V  | C<br>A<br>B<br>A<br>B  |
| Output current (sourcing and sinking)       | $R_L = 25\Omega$ , based on $V_{OUT}$ tests<br>$T_A = -40^\circ C$ to $+85^\circ C$  | <b><math>\pm 182</math></b><br>$\pm 176$  | $\pm 188$  |  | mA<br>mA   | A<br>B   |
| Short-circuit output current                |  |   | $\pm 1$  |  | A  | C  |
| Output impedance                            | $f = 1MHz$ , differential  |   | 0.2  |  | $\Omega$   | C  |
| Crosstalk                                   | $f = 1MHz$ , $V_{OUT} = 2V_{PP}$ , Port 1 to Port 2  |   | -90  |  | dB   | C  |
| <b>POWER SUPPLY</b>                         |  |   |  |  |  |  |
| Operating voltage                           | $T_A = -40^\circ C$ to $+85^\circ C$   | <b><math>\pm 5</math></b><br>$\pm 5$  | $\pm 6$  | <b><math>\pm 14</math></b><br>$\pm 14$   | V<br>V   | A<br>C   |
| $I_{S+}$ Quiescent current                  | Per port, full bias (Bias-1 = 0, Bias-2 = 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, mid bias (Bias-1 = 1, Bias-2 = 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, low bias (Bias-1 = 0, Bias-2 = 1)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, bias off (Bias-1 = 1, Bias-2 = 1)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, full bias (Bias-1 = 0, Bias-2 = 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, mid bias (Bias-1 = 1, Bias-2 = 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, low bias (Bias-1 = 0, Bias-2 = 1)<br>$T_A = -40^\circ C$ to $+85^\circ C$<br>Per port, bias off (Bias-1 = 1, Bias-2 = 1)<br>$T_A = -40^\circ C$ to $+85^\circ C$ | <b>13</b><br>10<br><b>10.2</b><br>9.3<br>6.7<br>0.5<br><b>12</b><br>9<br><b>9.2</b><br>8.3<br>6.4<br>5.7<br>0.1<br><b>54</b><br>52<br><b>52</b><br>50 | 17<br>22<br>13.2<br>16.4<br>11.6<br>0.9<br>16<br>21<br>12.2<br>15.4<br>8.4<br>10.6<br>0.5<br>1<br>64<br>63<br>50 | <b>21</b><br><b>16.2</b><br><b>11.4</b><br><b>0.8</b><br><b>20</b><br><b>15.2</b><br><b>10.4</b><br><b>0.3</b> | mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>dB<br>dB<br>dB | A<br>A<br>A<br>B<br>A<br>B<br>A<br>B<br>A<br>B<br>A<br>B<br>A<br>B<br>A<br>C<br>B<br>A |
| $I_{S-}$ Quiescent current                  |  |   |  |  |  |  |
| Current through GND pin                     | Per port, full bias (Bias-1 = 0, Bias-2 = 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$   |   | 1  |  | mA   | C  |
| Power-supply rejection ratio (+PSRR)        | Differential<br>$T_A = -40^\circ C$ to $+85^\circ C$   | <b>54</b><br>52   | 64   |  | dB   | A  |
| Power-supply rejection ratio (-PSRR)        | Differential<br>$T_A = -40^\circ C$ to $+85^\circ C$   | <b>52</b><br>50   | 63   |  | dB   | A  |
|   |  |   |  |  | dB   | B  |

(2) Test circuit is shown in [Figure 1](#).

## ELECTRICAL CHARACTERISTICS: $V_S = \pm 6V$ (continued)

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +5V/V$  with  $R_L = 100\Omega$  differential load,  $R_{ADJ} = 0\Omega$ , active impedance circuit configuration, and full bias, unless otherwise noted. Each port is independently tested.

| PARAMETER                         | CONDITIONS   | THS6214IRHF, IPWP |         |           | UNIT             | TEST LEVEL <sup>(1)</sup> |
|-----------------------------------|--|-------------------|---------|-----------|------------------|---------------------------|
|                                   |  | MIN               | TYP     | MAX       |                  |                           |
| <b>LOGIC</b>                      |  |                   |         |           |                  |                           |
| Bias control pin logic threshold  | Logic 1, with respect to GND <sup>(3)</sup> , $T_A = -40^\circ C$ to $+85^\circ C$<br>Logic 0, with respect to GND <sup>(3)</sup> , $T_A = -40^\circ C$ to $+85^\circ C$ | 1.9               |         | 0.8       | V                | B                         |
|                                   | Bias-1, Bias-2 = 0.5V (logic 0)<br>$T_A = -40^\circ C$ to $+85^\circ C$  |                   | 20      | <b>30</b> | $\mu A$          | A                         |
| Bias pin quiescent current        | Bias-1, Bias-2 = 3.3V (logic 1)<br>$T_A = -40^\circ C$ to $+85^\circ C$  |                   | 0.3     | <b>1</b>  | $\mu A$          | A                         |
| Turn-on time delay ( $t_{ON}$ )   | Time for $I_S$ to reach 50% of final value   |                   | 1       |           | $\mu s$          | C                         |
| Turn-off time delay ( $t_{OFF}$ ) | Time for $I_S$ to reach 50% of final value   |                   | 1       |           | $\mu s$          | C                         |
| Bias pin input impedance          |  |                   | 50      |           | k $\Omega$       | C                         |
| Amplifier output impedance        | Off bias (Bias-1 = 1, Bias-2 = 1)  |                   | 10    5 |           | k $\Omega$    pF | C                         |

(3) The GND pin usable range is from  $V_{S-}$  to  $(V_{S+} - 5V)$ .

**Table 1. Logic Table**

| BIAS-1 | BIAS-2 | FUNCTION              | DESCRIPTION  |
|--------|--------|-----------------------|--|
| 0      | 0      | Full bias mode (100%) | Amplifiers on with lowest distortion possible (default state)                    |
| 1      | 0      | Mid bias mode (75%)   | Amplifiers on with power savings and a reduction in distortion performance       |
| 0      | 1      | Low bias mode (50%)   | Amplifiers on with enhanced power savings and a reduction of overall performance |
| 1      | 1      | Shutdown mode         | Amplifiers off and output has high impedance                                     |

### TYPICAL CHARACTERISTICS: $V_S = \pm 12V$ , Full Bias

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +10V/V$ ,  $G_{CM} = 1V/V$ ,  $R_{ADJ} = 0\Omega$ ,  $R_F = 1.24k\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

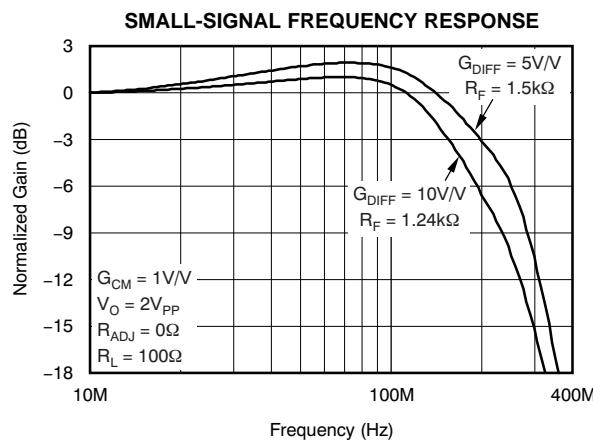


Figure 2.

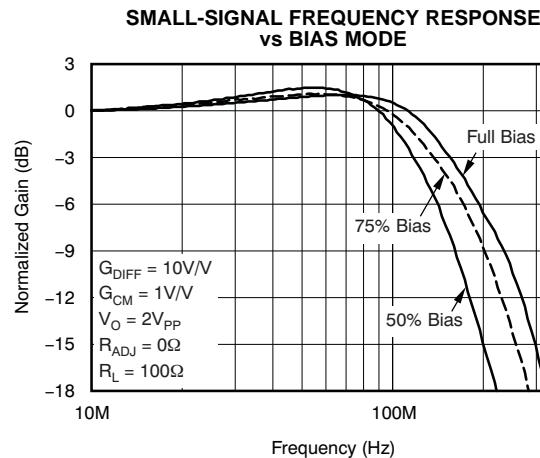


Figure 3.

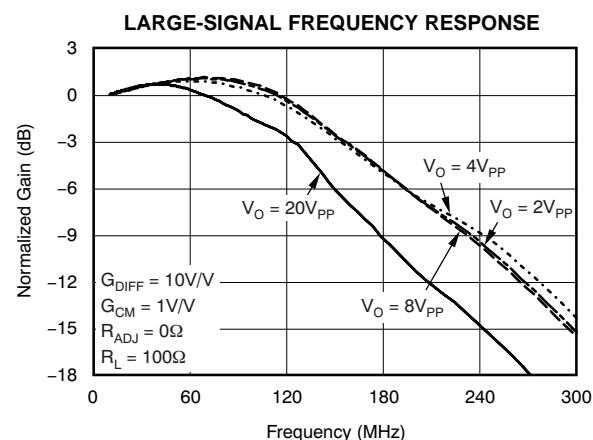


Figure 4.

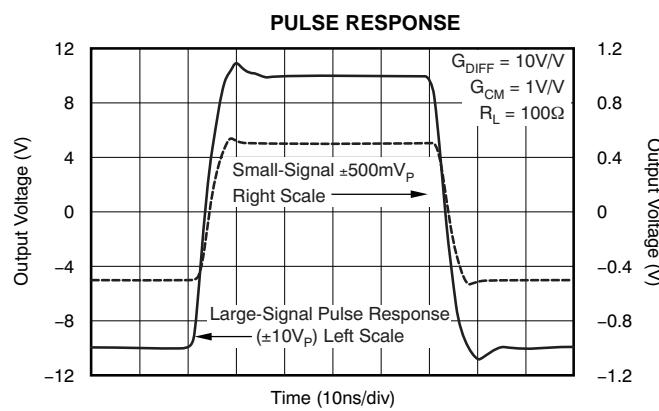


Figure 5.

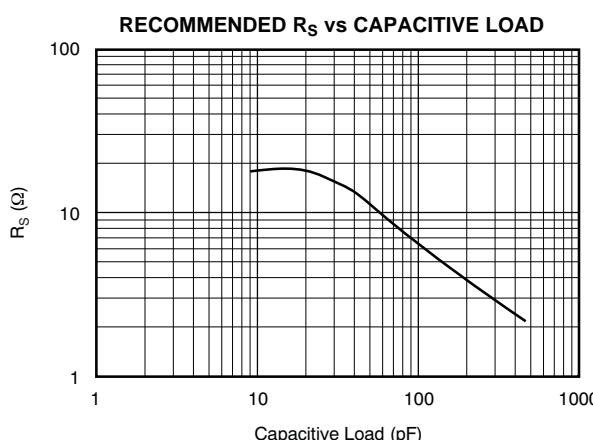


Figure 6.

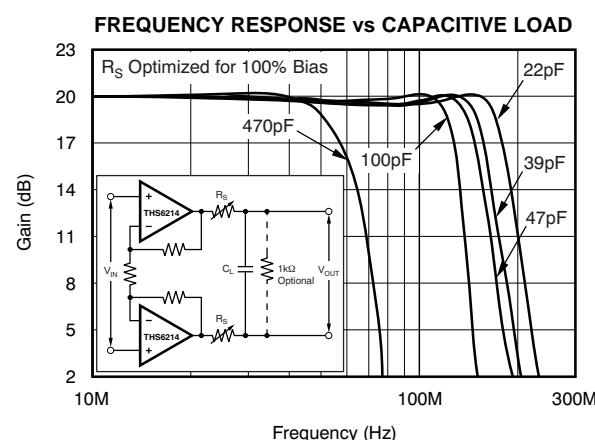


Figure 7.

**TYPICAL CHARACTERISTICS:  $V_S = \pm 12V$ , Full Bias (continued)**

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +10V/V$ ,  $G_{CM} = 1V/V$ ,  $R_{ADJ} = 0\Omega$ ,  $R_F = 1.24k\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

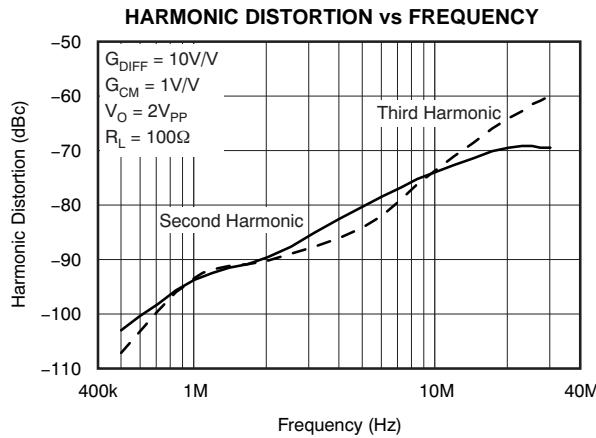


Figure 8.

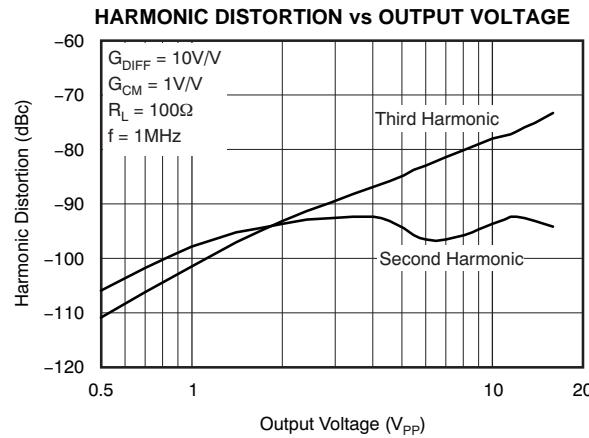


Figure 9.

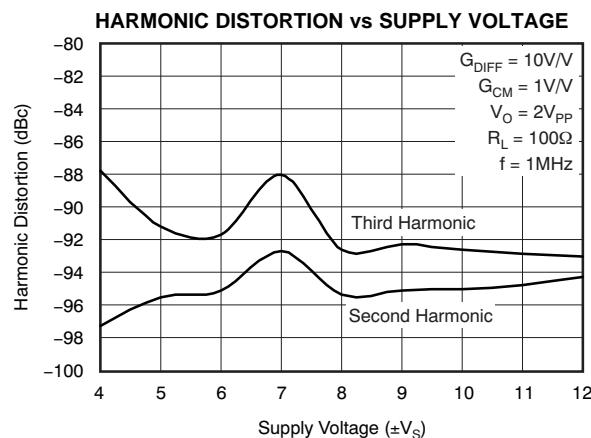


Figure 10.

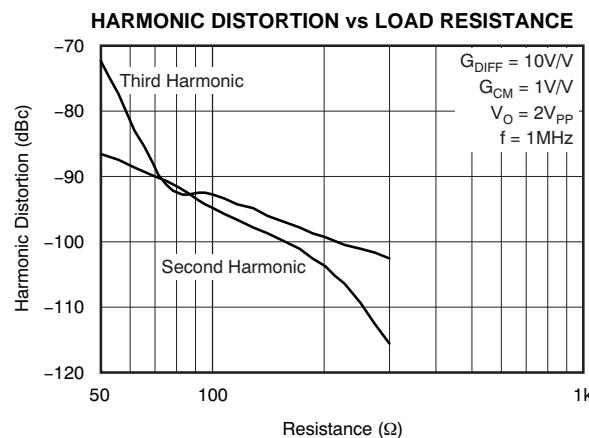


Figure 11.

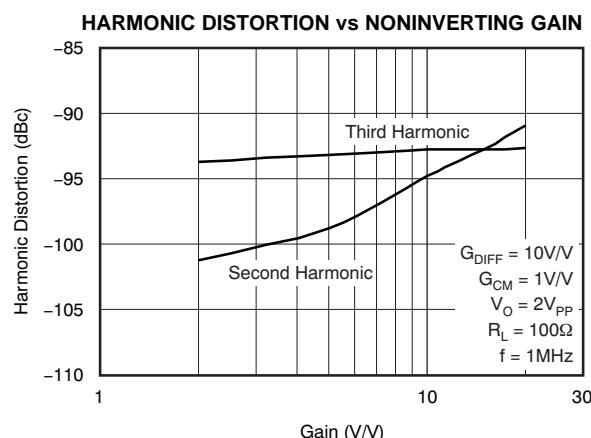


Figure 12.

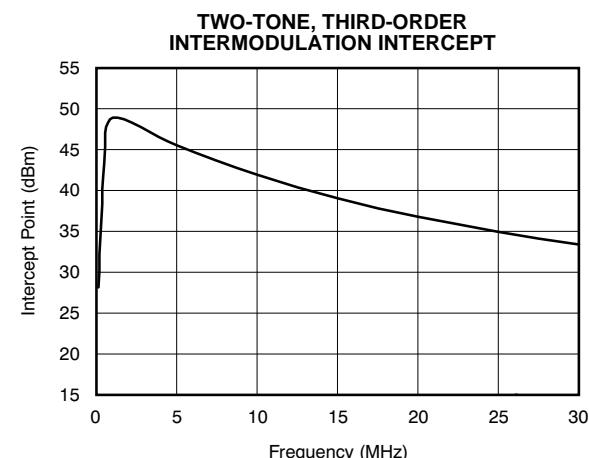


Figure 13.

**TYPICAL CHARACTERISTICS:  $V_S = \pm 12V$ , Full Bias (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +10\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.24\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

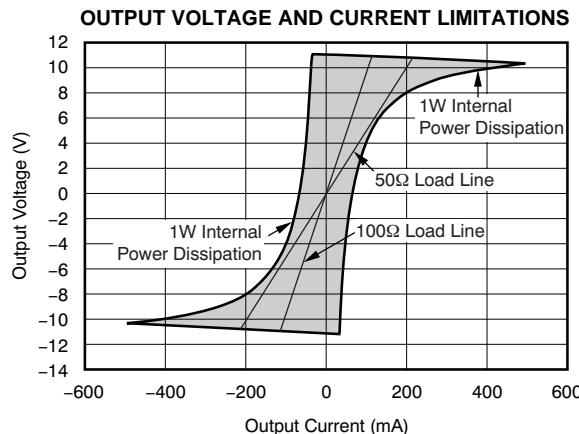


Figure 14.

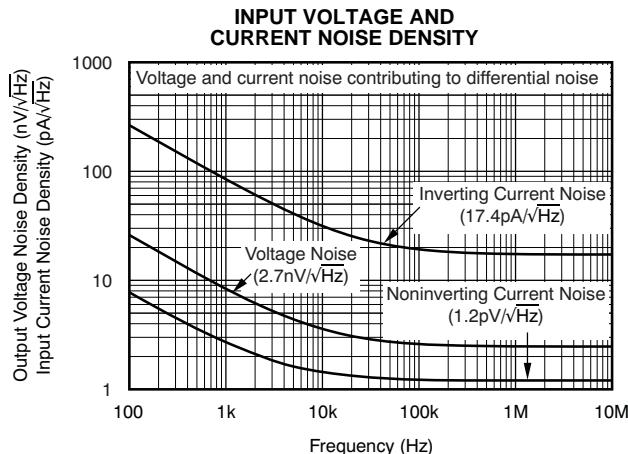


Figure 15.

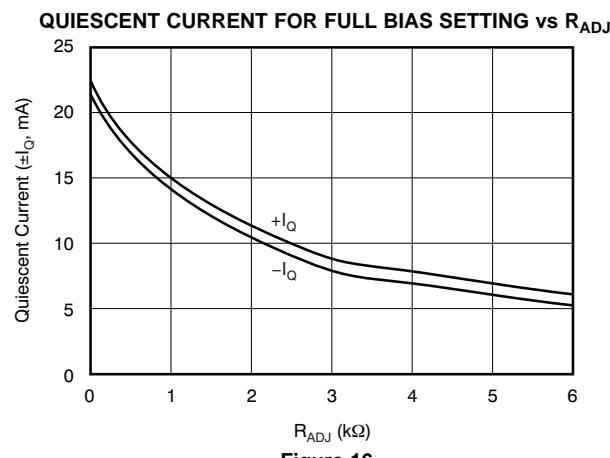


Figure 16.

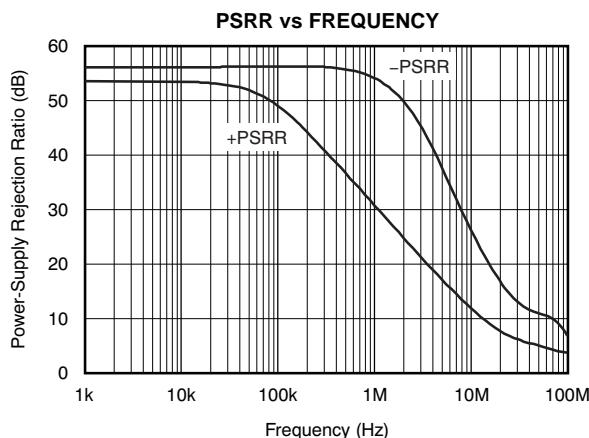


Figure 17.

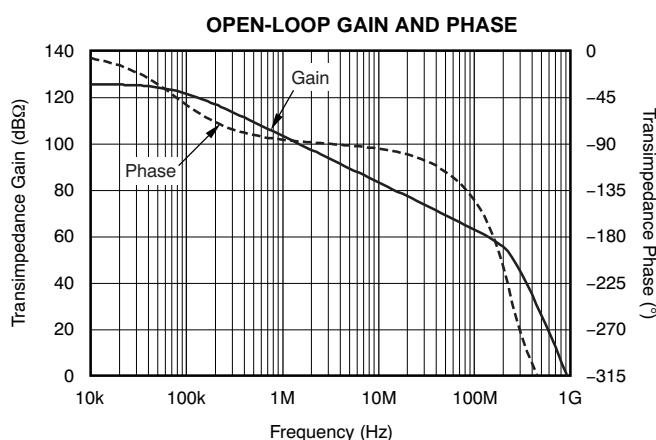


Figure 18.

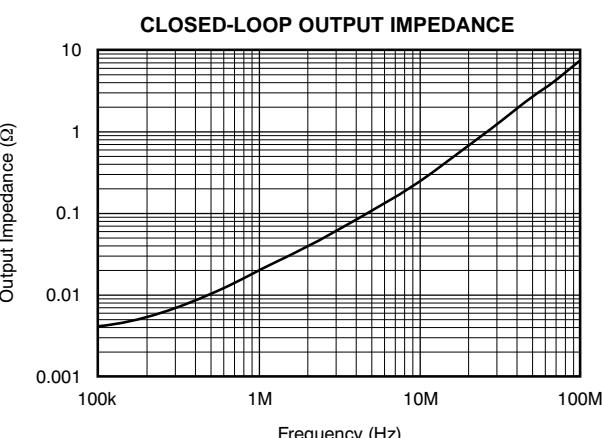


Figure 19.

### TYPICAL CHARACTERISTICS: $V_S = \pm 12V$ , Mid Bias

At  $T_A = +25^\circ C$ ,  $G_{DIFF} = +10V/V$ ,  $G_{CM} = 1V/V$ ,  $R_{ADJ} = 0\Omega$ ,  $R_F = 1.24k\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

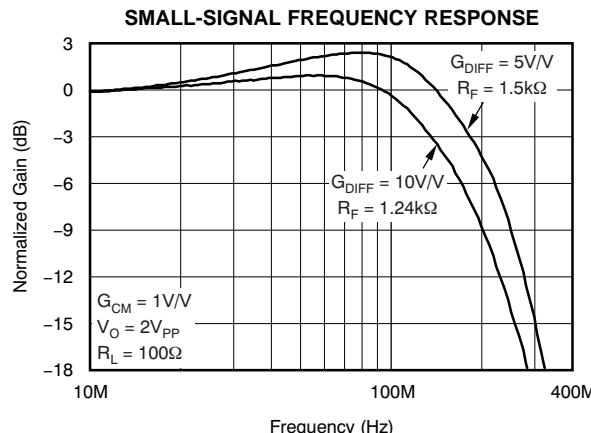


Figure 20.

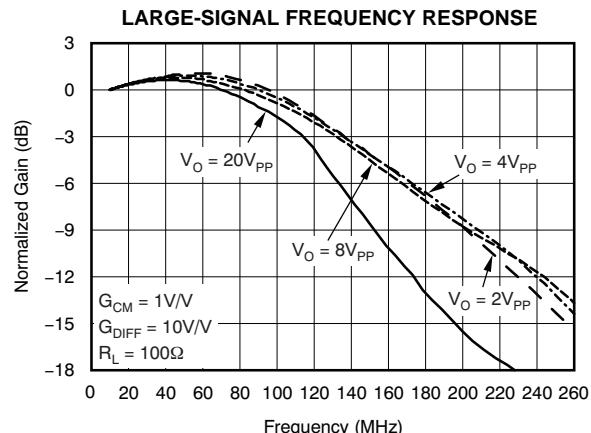


Figure 21.

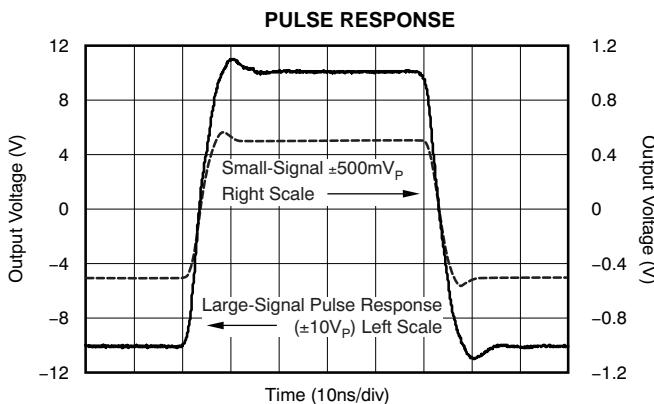


Figure 22.

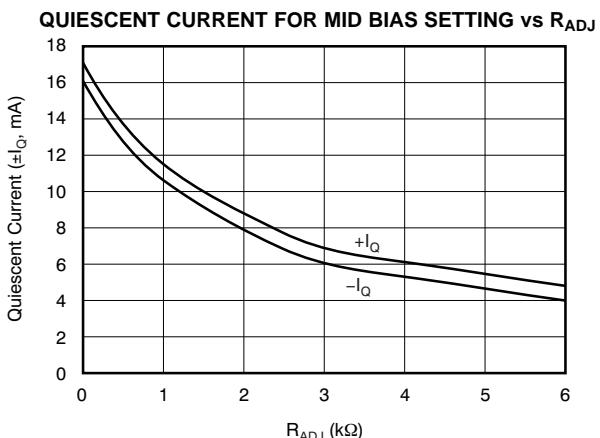


Figure 23.

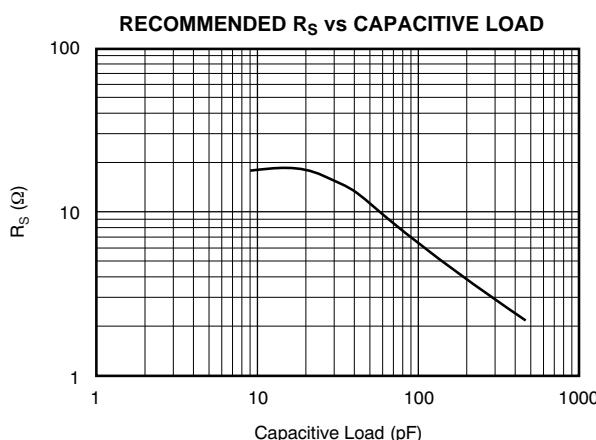


Figure 24.

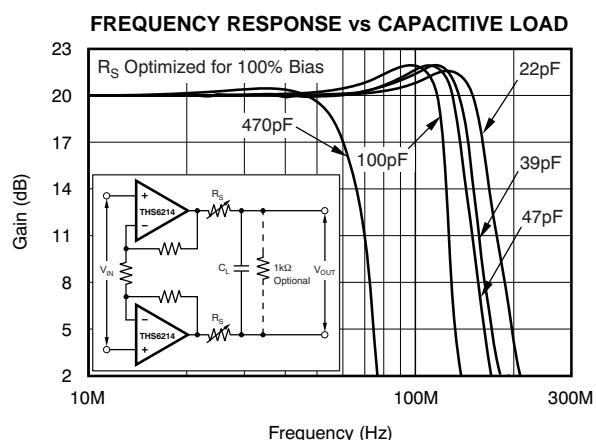


Figure 25.

**TYPICAL CHARACTERISTICS:  $V_S = \pm 12V$ , Mid Bias (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +10\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.24\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

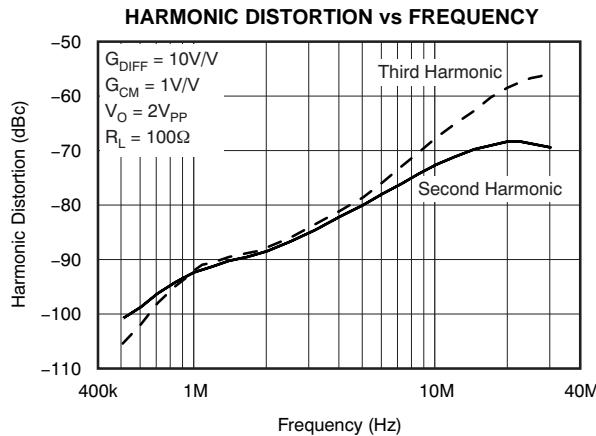


Figure 26.

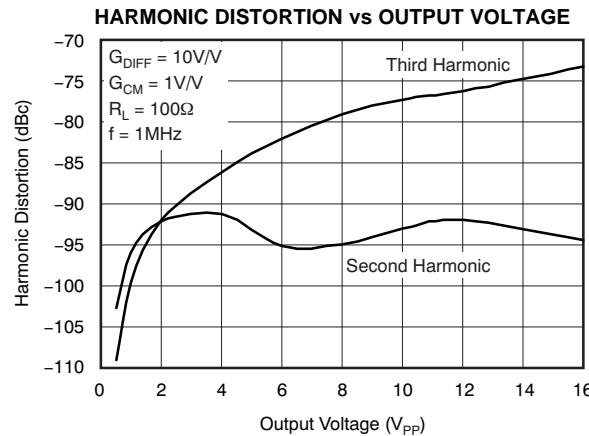


Figure 27.

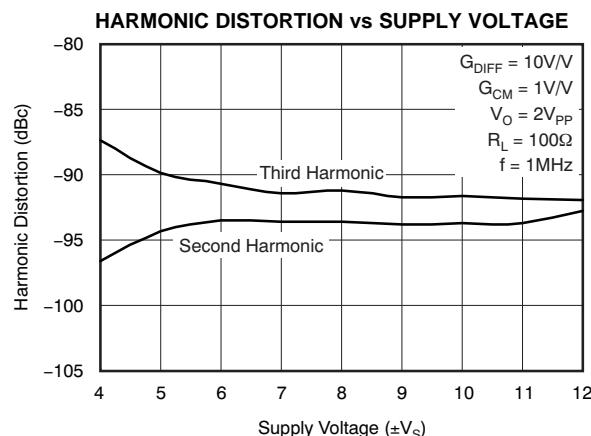


Figure 28.

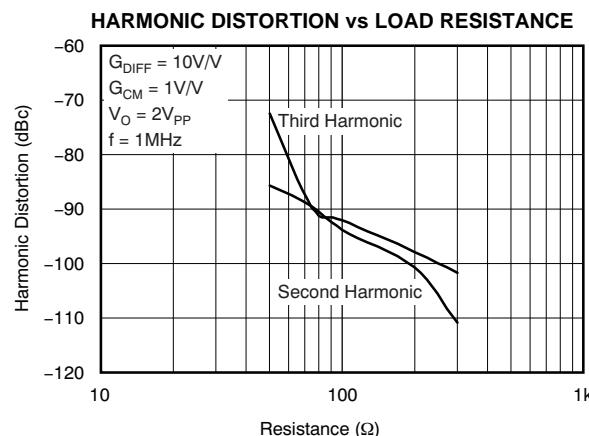


Figure 29.

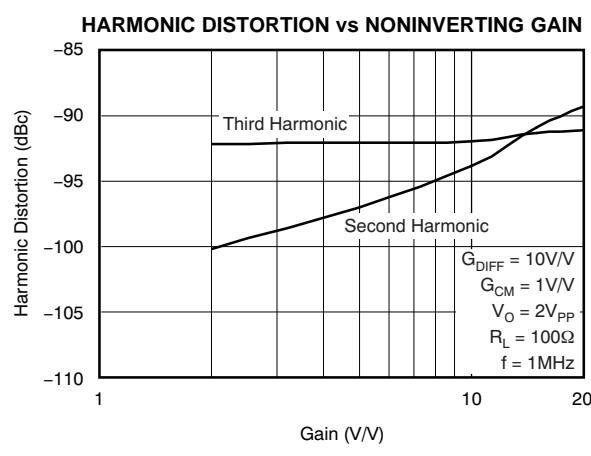


Figure 30.

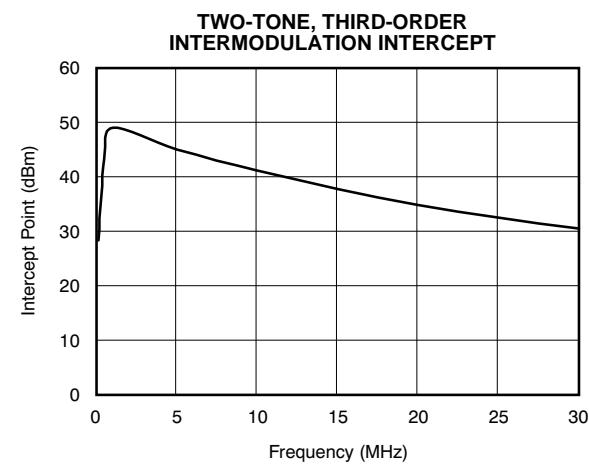
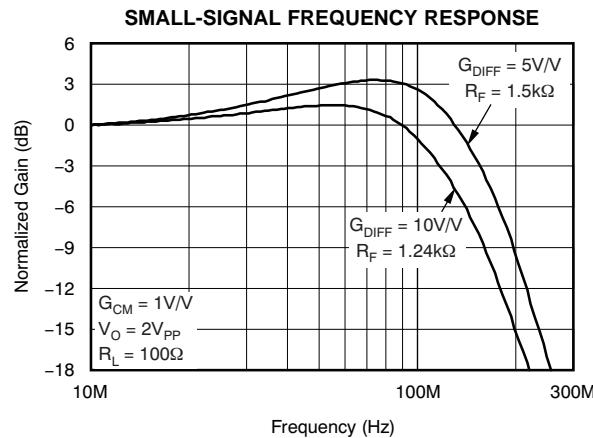


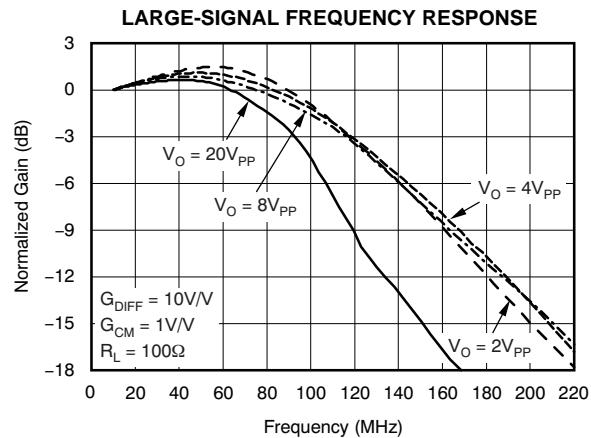
Figure 31.

**TYPICAL CHARACTERISTICS:  $V_S = \pm 12V$ , Low Bias**

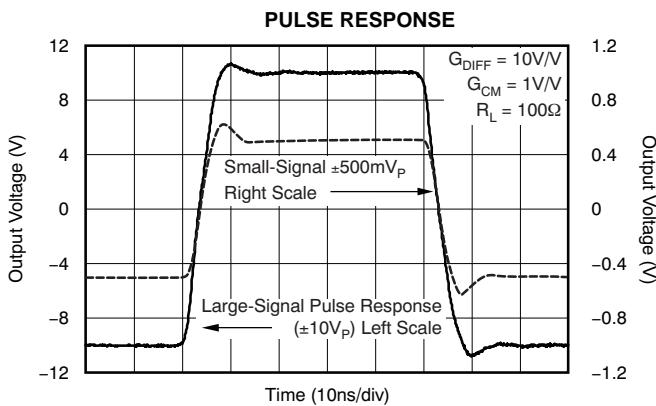
At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +10\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.24\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.



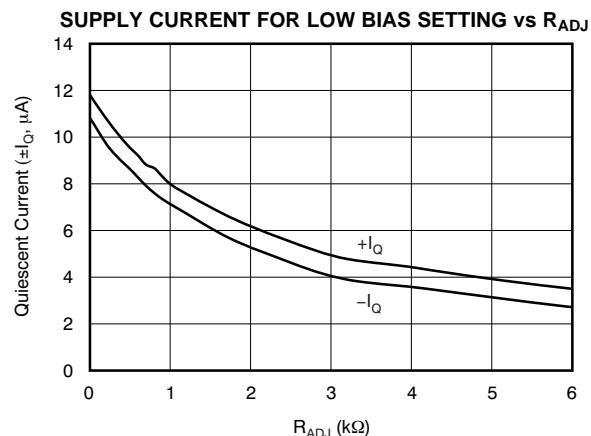
**Figure 32.**



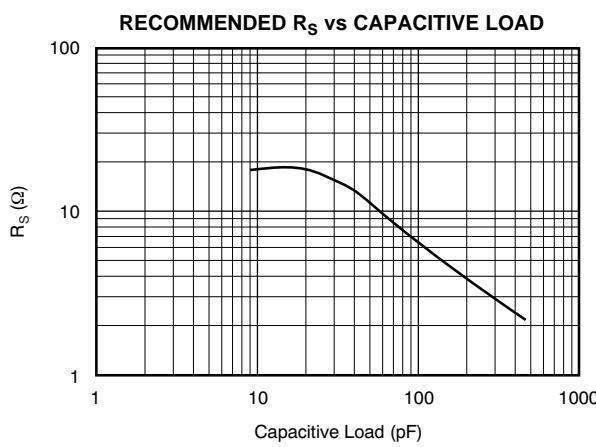
**Figure 33.**



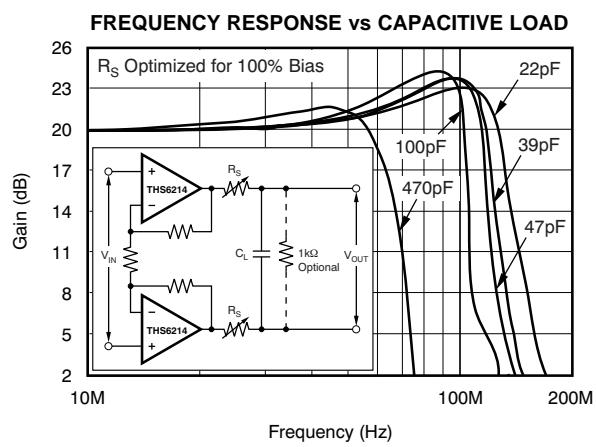
**Figure 34.**



**Figure 35.**



**Figure 36.**



**Figure 37.**

### TYPICAL CHARACTERISTICS: $V_S = \pm 12V$ , Low Bias (continued)

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +10\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.24\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

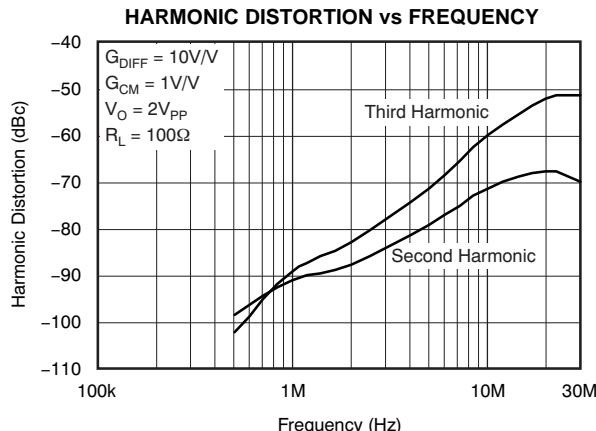


Figure 38.

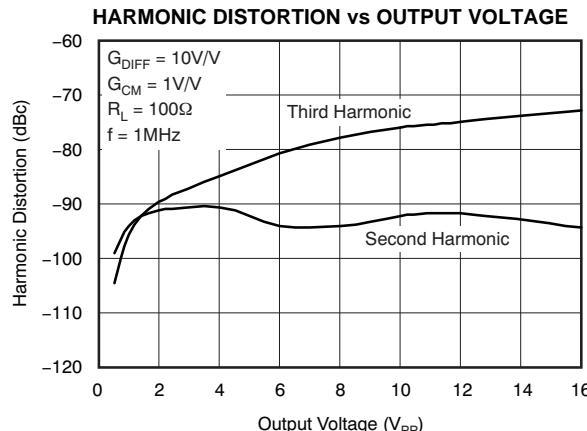


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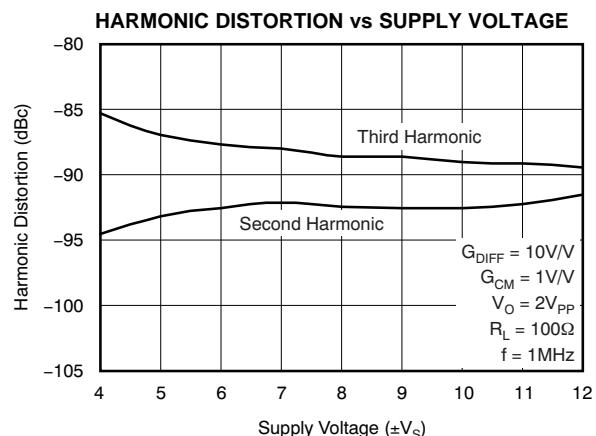


Figure 40.

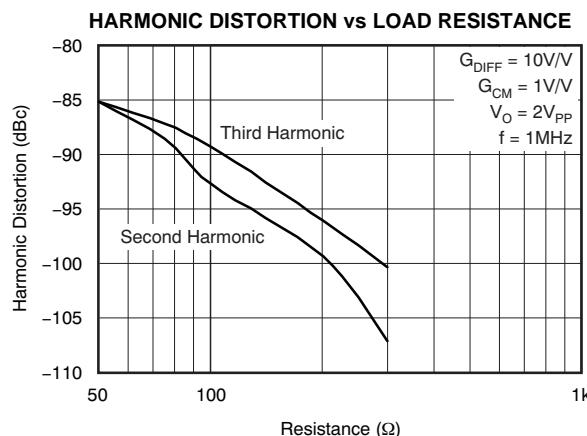


Figure 41.

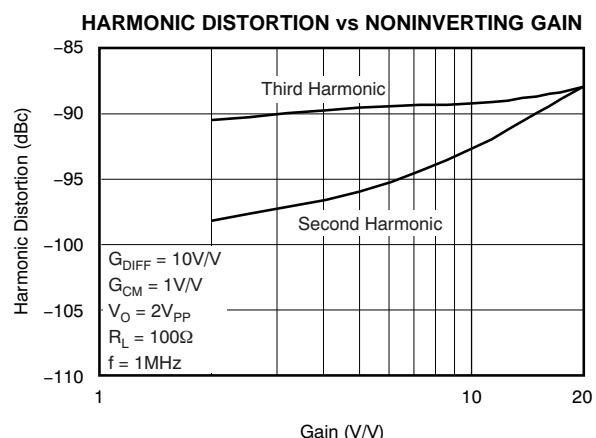


Figure 42.

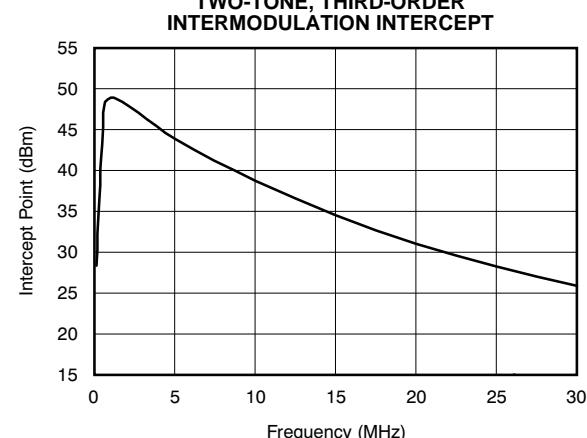


Figure 43.

**TYPICAL CHARACTERISTICS:  $V_S = \pm 6V$ , Full Bias**

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

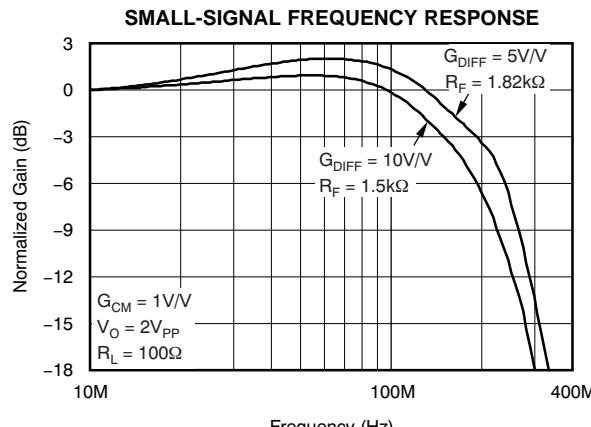


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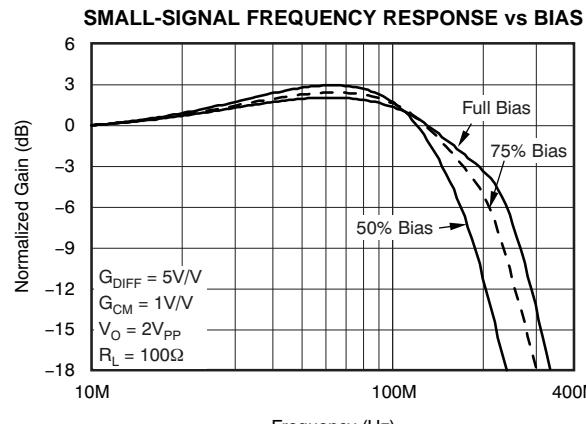


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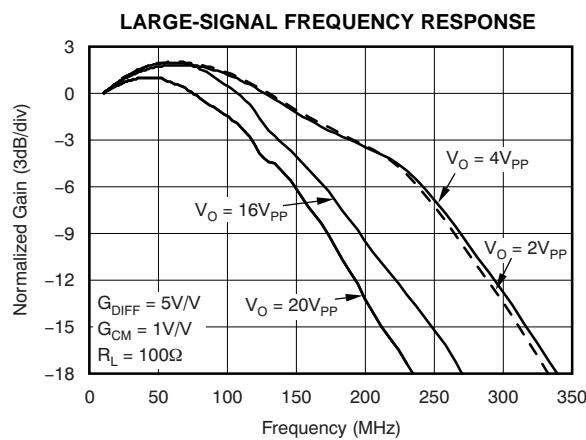


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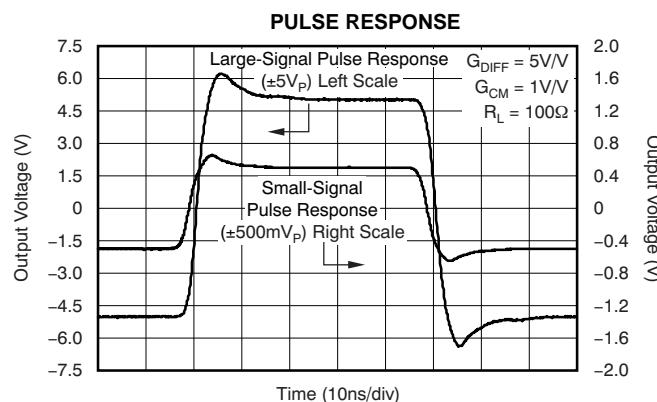


Figure 47.

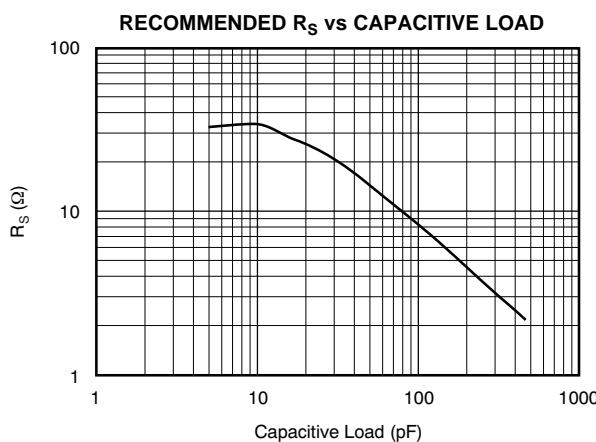


Figure 48.

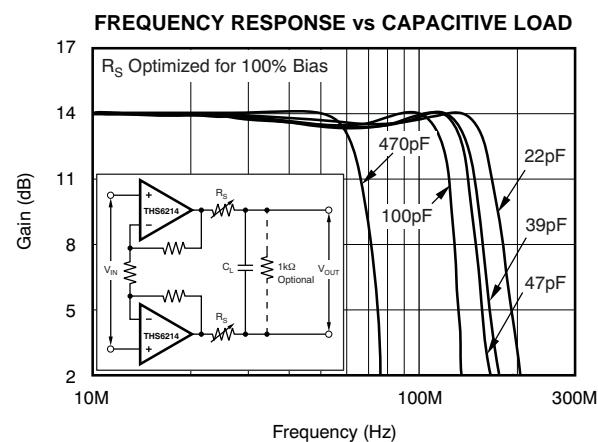


Figure 49.

### TYPICAL CHARACTERISTICS: $V_S = \pm 6V$ , Full Bias (continued)

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

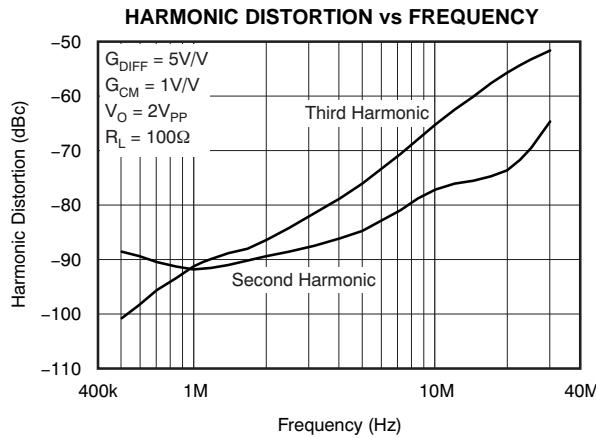


Figure 50.

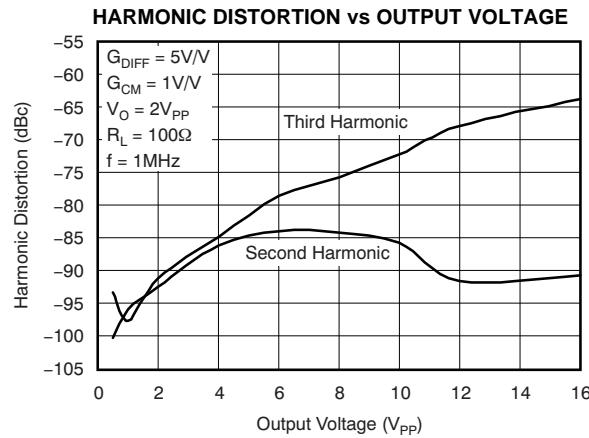


Figure 51.

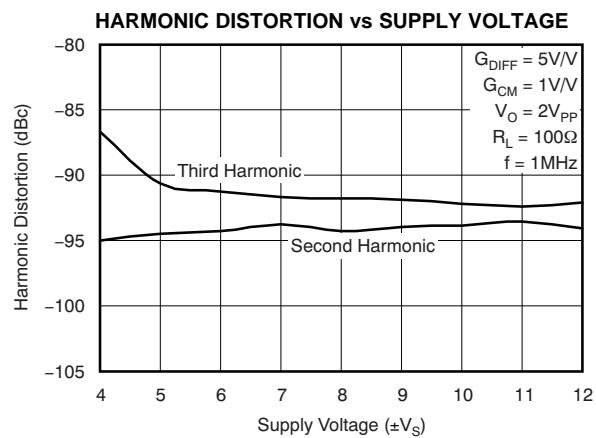


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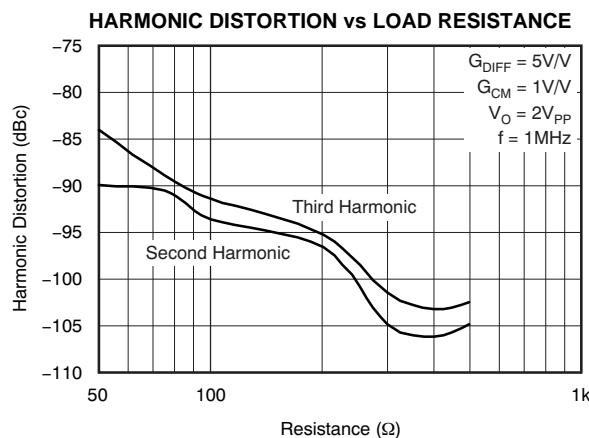


Figure 53.

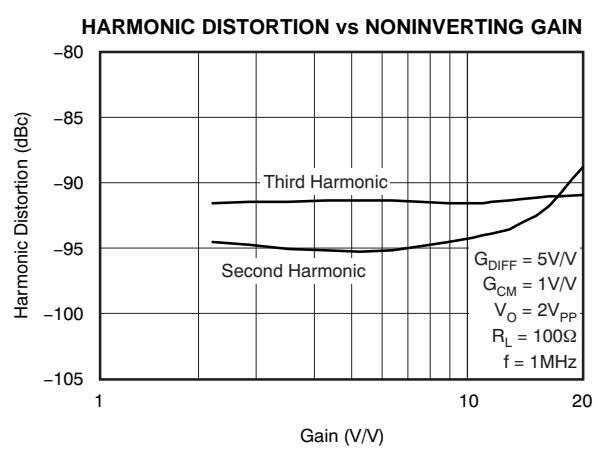


Figure 54.

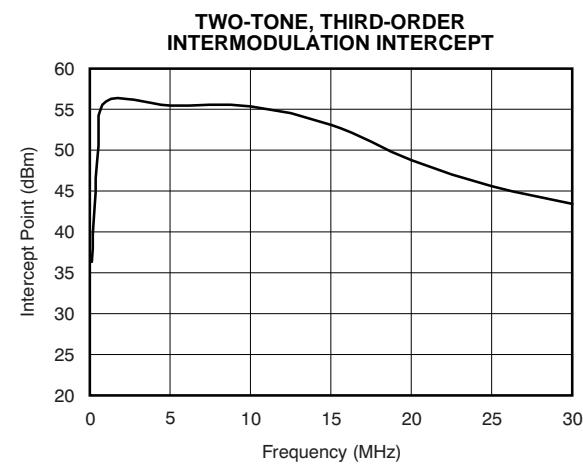
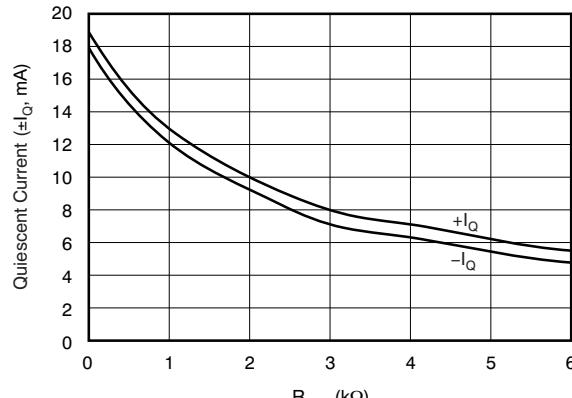


Figure 55.

**TYPICAL CHARACTERISTICS:  $V_S = \pm 6V$ , Full Bias (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

**QUIESCENT CURRENT FOR FULL BIAS SETTING vs  $R_{\text{ADJ}}$**



**Figure 56.**

### TYPICAL CHARACTERISTICS: $V_S = \pm 6V$ , Mid Bias

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

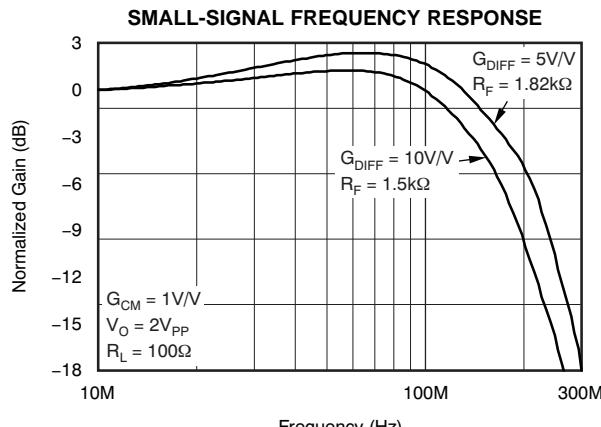


Figure 57.

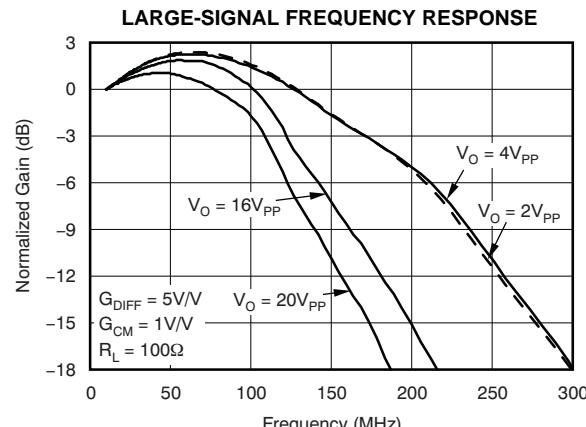


Figure 58.

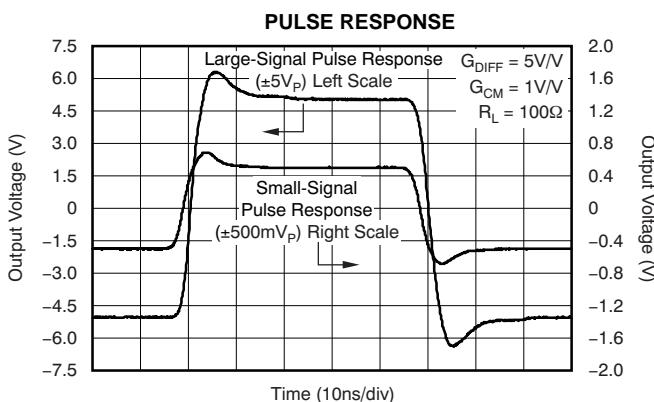


Figure 59.

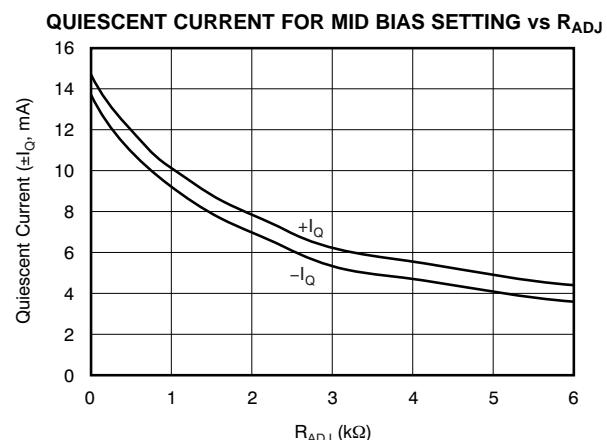


Figure 60.

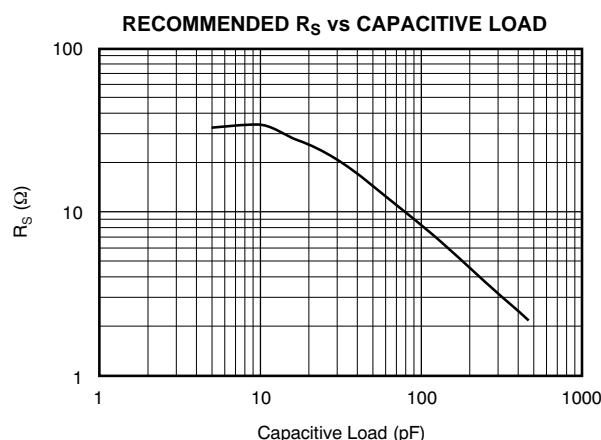


Figure 61.

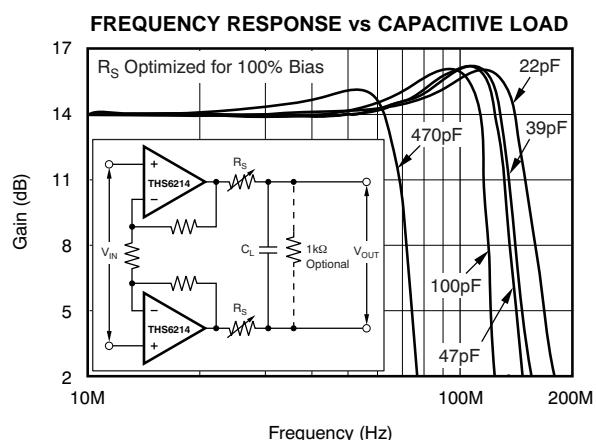


Figure 62.

### TYPICAL CHARACTERISTICS: $V_S = \pm 6V$ , Mid Bias (continued)

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

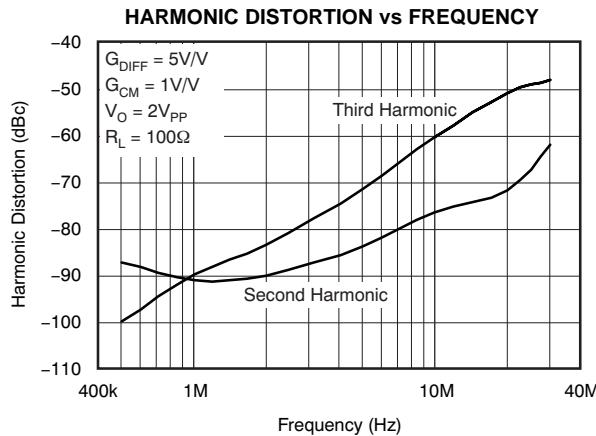


Figure 63.

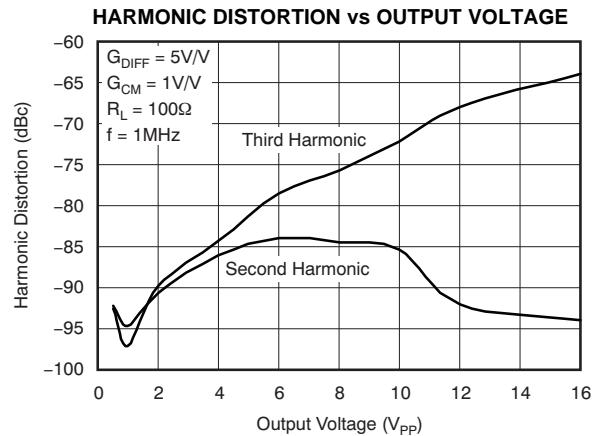


Figure 64.

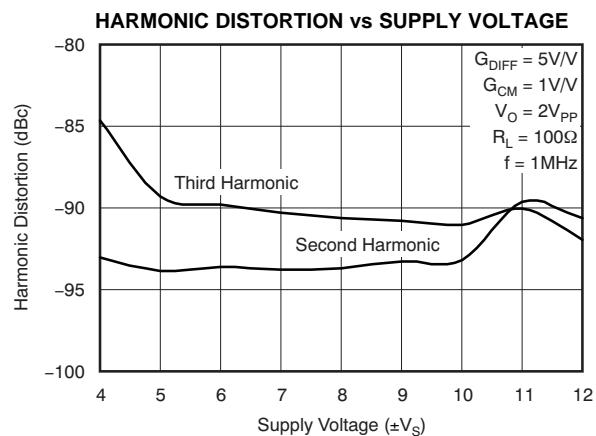


Figure 65.

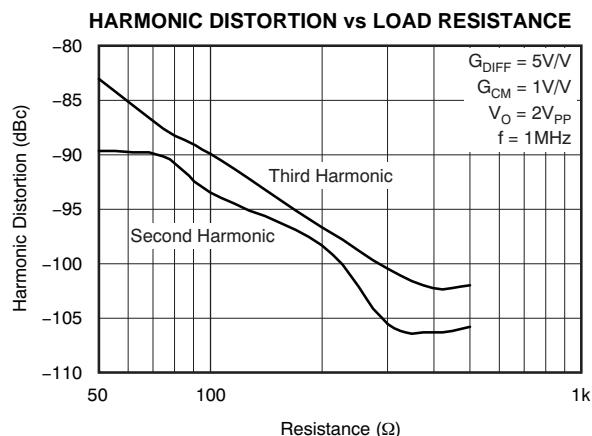


Figure 66.

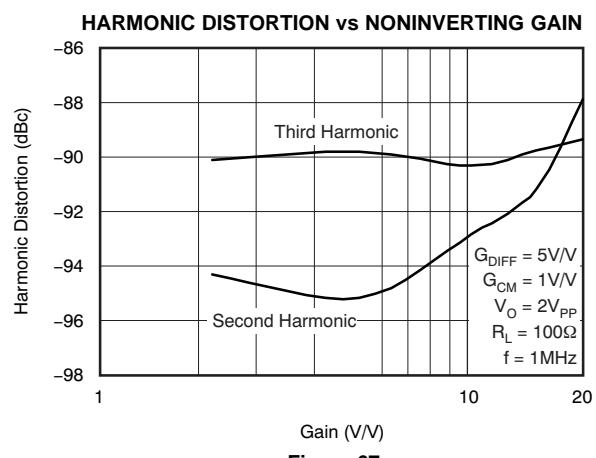


Figure 67.

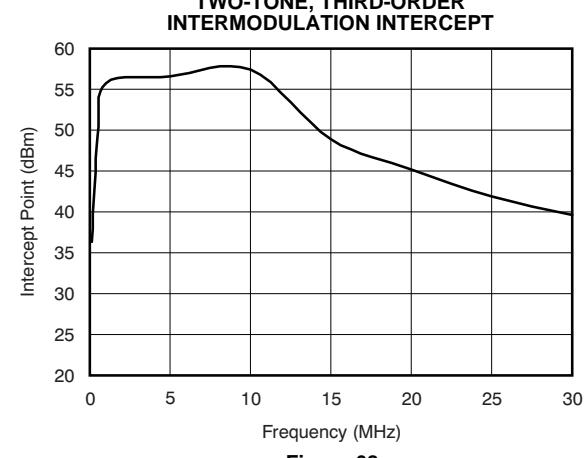


Figure 68.

### TYPICAL CHARACTERISTICS: $V_S = \pm 6V$ , Low Bias

At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.

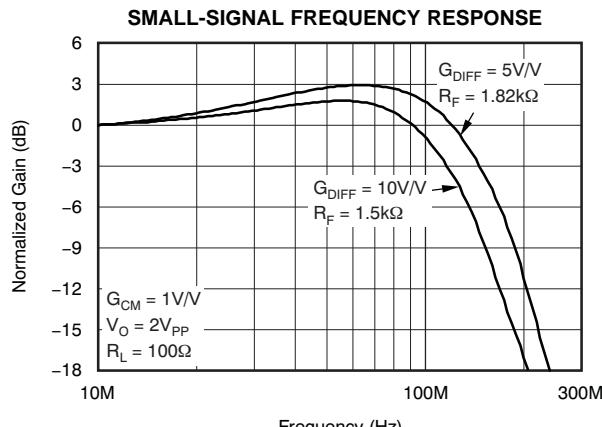


Figure 69.

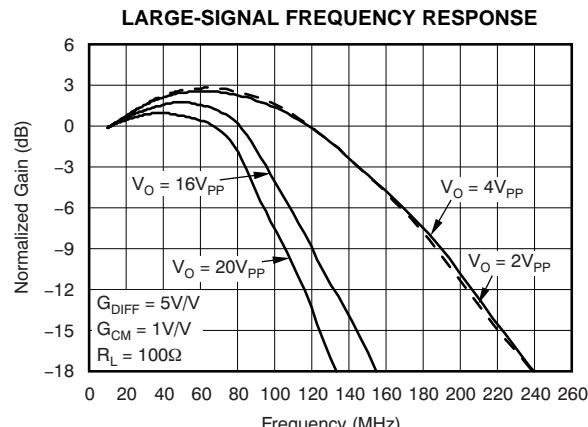


Figure 70.

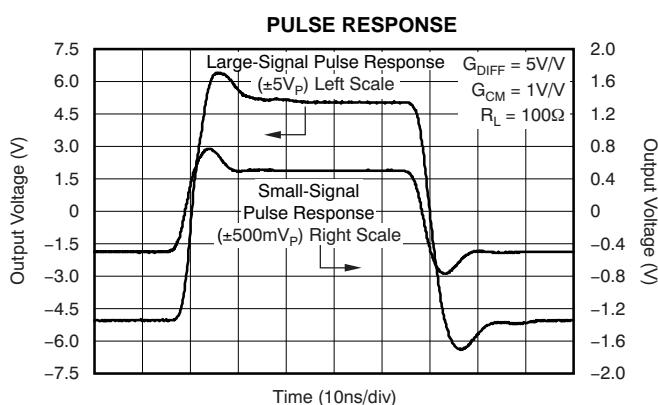


Figure 71.

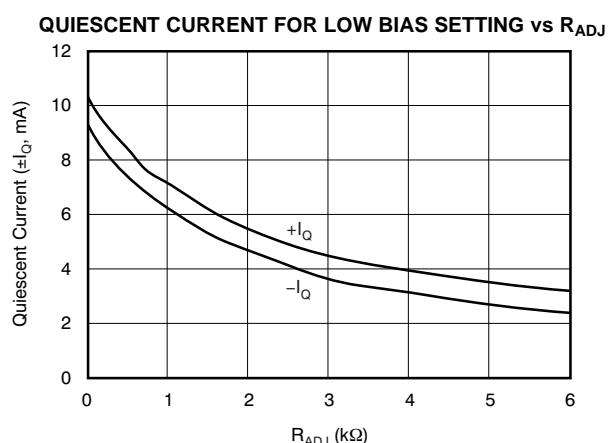


Figure 72.

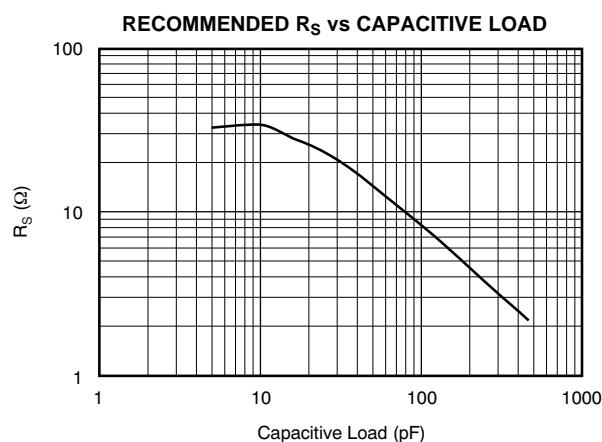


Figure 73.

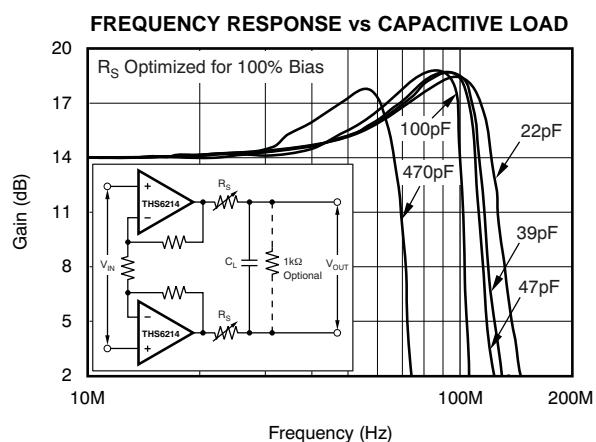
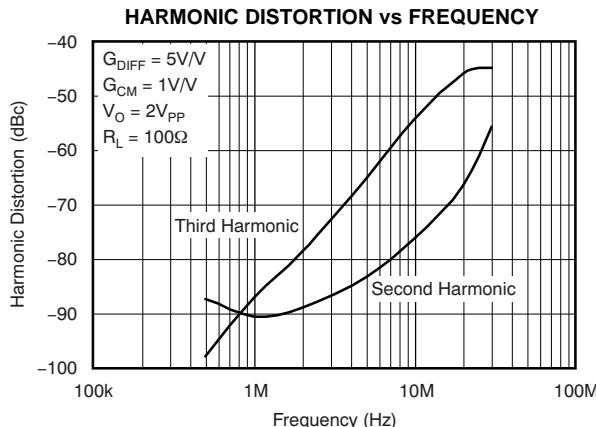


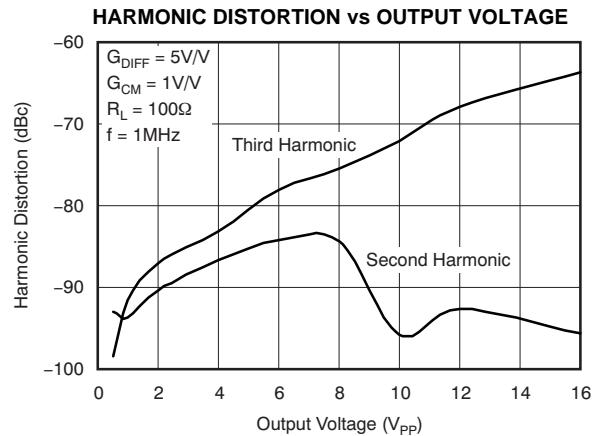
Figure 74.

### TYPICAL CHARACTERISTICS: $V_S = \pm 6V$ , Low Bias (continued)

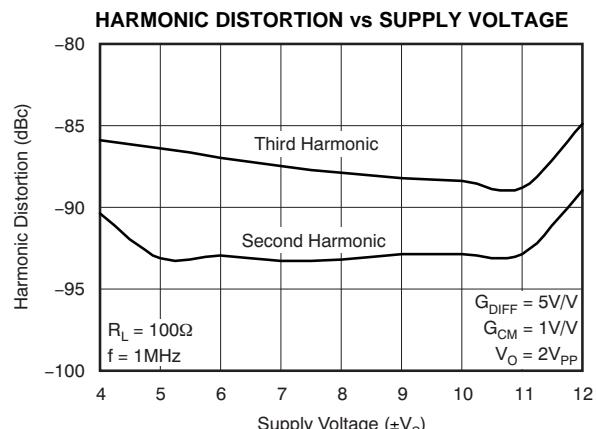
At  $T_A = +25^\circ\text{C}$ ,  $G_{\text{DIFF}} = +5\text{V/V}$ ,  $G_{\text{CM}} = 1\text{V/V}$ ,  $R_{\text{ADJ}} = 0\Omega$ ,  $R_F = 1.82\text{k}\Omega$ , and  $R_L = 100\Omega$ , unless otherwise noted.



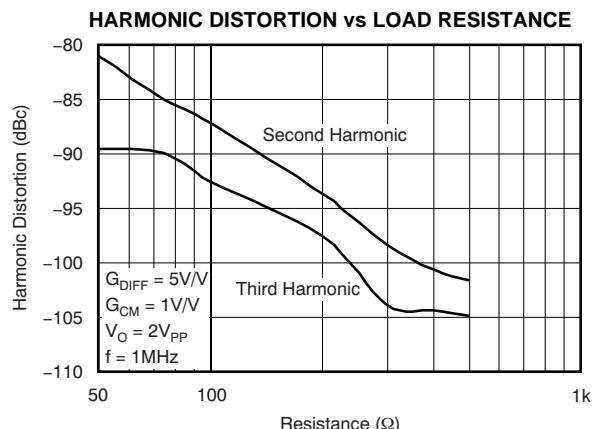
**Figure 75.**



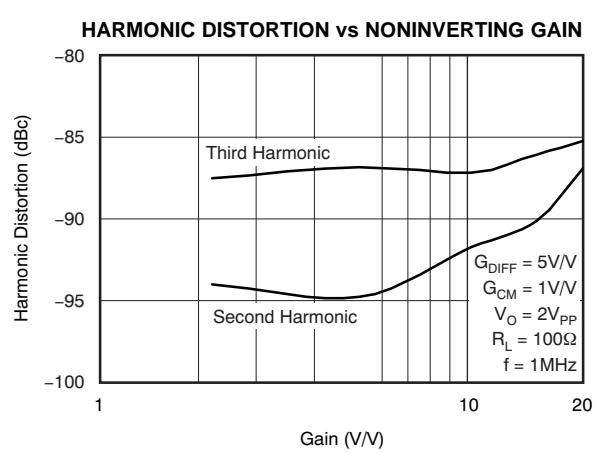
**Figure 76.**



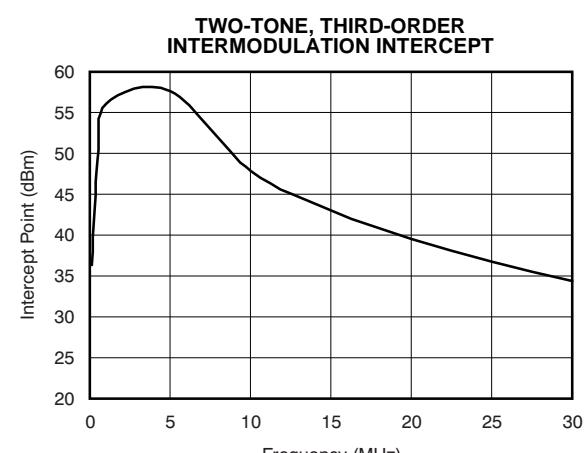
**Figure 77.**



**Figure 78.**



**Figure 79.**



**Figure 80.**

## APPLICATION INFORMATION

### WIDEBAND CURRENT-FEEDBACK OPERATION

The THS6214 provides the exceptional ac performance of a wideband current-feedback op amp with a highly linear, high-power output stage. Requiring only 21mA/port quiescent current, the THS6214 swings to within 1.9V of either supply rail on a 100Ω load and delivers in excess of 416mA at room temperature. This low-output headroom requirement, along with supply voltage independent biasing, provides remarkable  $\pm 6$ V supply operation. The THS6214 delivers greater than 140MHz bandwidth driving a 2V<sub>PP</sub> output into 100Ω on a  $\pm 6$ V supply. Previous boosted output stage amplifiers typically suffer from very poor crossover distortion as the output current goes through zero. The THS6214 achieves a comparable power gain with much better linearity. The primary advantage of a current-feedback op amp over a voltage-feedback op amp is that ac performance (bandwidth and distortion) is relatively independent of signal gain. Figure 81 shows the dc-coupled, gain of +10V/V, dual power-supply circuit configuration used as the basis of the  $\pm 12$ V Electrical and Typical Characteristics. For test purposes, the input impedance is set to 50Ω with a resistor to ground and the output impedance is set to 50Ω with a series output resistor. Voltage swings reported in the Electrical Characteristics are taken directly at the input and output pins, whereas load powers (dBm) are defined at a matched 50Ω load. For the circuit of Figure 81, the total effective load is  $100\Omega \parallel 1.24\text{k}\Omega \parallel 1.24\text{k}\Omega = 86.1\Omega$ .

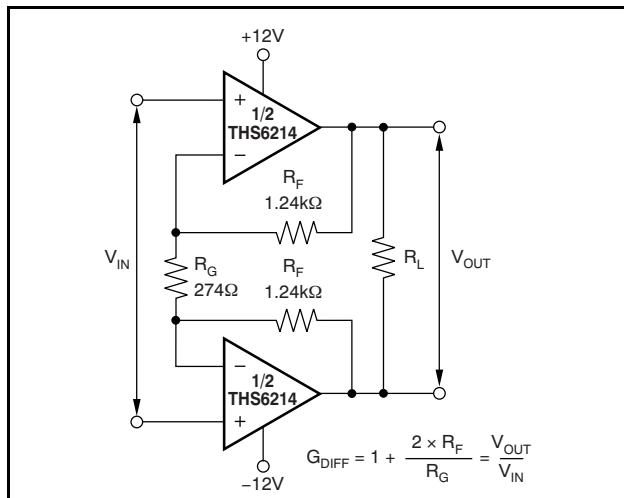


Figure 81. Noninverting Differential I/O Amplifier

This approach allows the user to set a source termination impedance at the input that is independent of the signal gain. For instance, simple differential filters may be included in the signal path right up to the noninverting inputs with no interaction with the gain setting. The differential signal gain for the circuit of Figure 81 is:

$$A_D = 1 + 2 \times \frac{R_F}{R_G} \quad (1)$$

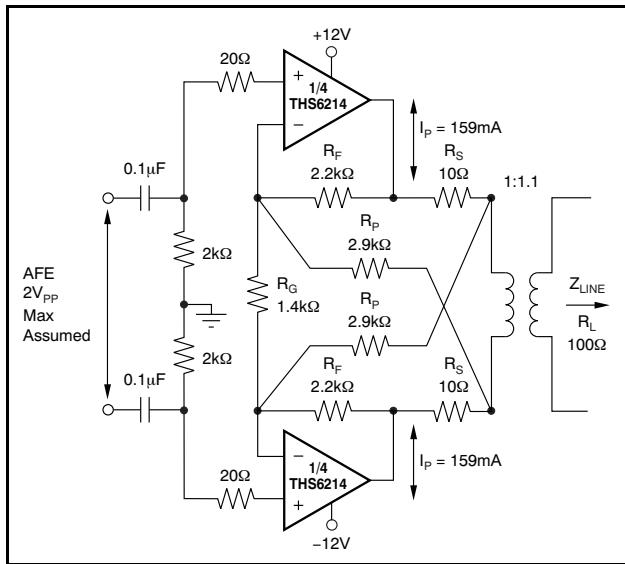
Where  $A_D$  = differential gain.

Figure 81 shows a value of 274Ω for the  $A_D = +10$ V/V design. Because the THS6214 is a current feedback (CFB) amplifier, its bandwidth is primarily controlled with the feedback resistor value; the differential gain, however, may be adjusted with considerable freedom using just the  $R_G$  resistor. In fact,  $R_G$  may be reduced by a reactive network that provides a very isolated shaping to the differential frequency response.

Various combinations of single-supply or ac-coupled gain can also be delivered using the basic circuit of Figure 81. Common-mode bias voltages on the two noninverting inputs pass on to the output with a gain of +1V/V because an equal dc voltage at each inverting node creates no current through  $R_G$ . This circuit does show a common-mode gain of +1V/V from input to output. The source connection should either remove this common-mode signal if undesired (using an input transformer can provide this function), or the common-mode voltage at the inputs can be used to set the output common-mode bias. If the low common-mode rejection of this circuit is a problem, the output interface can also be used to reject that common-mode. For instance, most modern differential input analog-to-digital converters (ADCs) reject common-mode signals very well, while a line driver application through a transformer also attenuates the common-mode signal through to the line.

## DUAL-SUPPLY VDSL DOWNSTREAM

Figure 82 shows an example of a dual-supply VDSL downstream driver. Both channels of the THS6214 are configured as a differential gain stage to provide signal drive to the primary winding of the transformer (in Figure 82, a step-up transformer with a turns ratio of 1:1.1). The main advantage of this configuration is the cancellation of all even harmonic-distortion products. Another important advantage for VDSL is that each amplifier must only swing half of the total output required driving the load.



**Figure 82. Dual-Supply VDSL Downstream Driver**

The analog front-end (AFE) signal is ac-coupled to the driver, and the noninverting input of each amplifier is biased to the mid-supply voltage (ground in this case). In addition to providing the proper biasing to the amplifier, this approach also provides a high-pass filtering with a corner frequency, set here at 5kHz. Because the signal bandwidth starts at 26kHz, this high-pass filter does not generate any problem and has the advantage of filtering out unwanted lower frequencies.

The input signal is amplified with a gain set by the following equation:

$$G_D = 1 + \frac{2 \times R_F}{R_G} \quad (2)$$

With  $R_F = 2.2\text{k}\Omega$  and  $R_G = 1.4\text{k}\Omega$ , the gain for this differential amplifier is  $R_P = 2.9\text{k}\Omega$ . This gain boosts the AFE signal, assumed to be a maximum of  $2V_{PP}$ , to a maximum of  $3V_{PP}$ .

The two back-termination resistors ( $R_S = 10\Omega$  each) added at each terminal of the transformer make the impedance of the modem match the impedance of the phone line, and also provide a means of detecting the received signal for the receiver. The value of these resistors ( $R_M$ ) is a function of the line impedance and the transformer turns ratio ( $n$ ), given by the following equation:

$$R_M = \frac{Z_{LINE}}{2n^2} \quad (3)$$

## LINE DRIVER HEADROOM MODEL

The first step in a transformer-coupled, twisted-pair driver design is to compute the peak-to-peak output voltage from the target specifications. This calculation is done using the following equations:

$$P_L = 10 \times \log \frac{V_{RMS}^2}{(1\text{mW}) \times R_L} \quad (4)$$

with:

- $P_L$  = power at the load
- $V_{RMS}$  = voltage at the load
- $R_L$  = load impedance

These values produce the following:

$$V_{RMS} = \sqrt{(1\text{mW}) \times R_L \times 10 \frac{P_L}{10}} \quad (5)$$

$$V_P = \text{CrestFactor} \times V_{RMS} = CF \times V_{RMS} \quad (6)$$

with:

- $V_P$  = peak voltage at the load
- $CF$  = Crest Factor

$$V_{LPP} = 2 \times CF \times V_{RMS} \quad (7)$$

with  $V_{LPP}$  = peak-to-peak voltage at the load.

Consolidating Equation 4 through Equation 7 allows us to express the required peak-to-peak voltage at the load as a function of the crest factor, the load impedance, and the power at the load. Thus:

$$V_{LPP} = 2 \times CF \times \sqrt{(1\text{mW}) \times R_L \times 10 \frac{P_L}{10}} \quad (8)$$

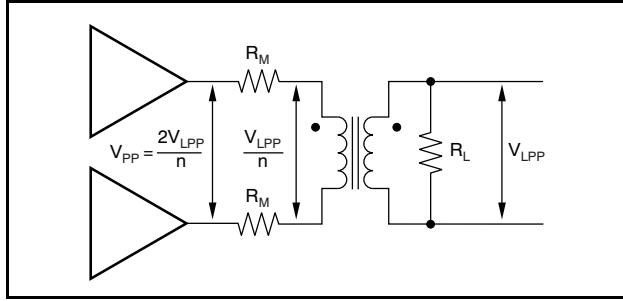
$V_{LPP}$  is usually computed for a nominal line impedance and may be taken as a fixed design target.

The next step in the design is to compute the individual amplifier output voltage and currents as a function of peak-to-peak voltage on the line and transformer turns ratio.

As this turns ratio changes, the minimum allowed supply voltage changes along with it. The peak current in the amplifier output is given by:

$$\pm I_P = \frac{1}{2} \times \frac{2 \times V_{LPP}}{n} \times \frac{1}{4R_M} \quad (9)$$

with  $V_{PP}$  as defined in [Equation 8](#), and  $R_M$  as defined in [Equation 3](#) and shown in [Figure 83](#).



**Figure 83. Driver Peak Output Voltage**

With the previous information available, it is now possible to select a supply voltage and the turns ratio desired for the transformer, as well as calculate the headroom for the THS6214.

The model, shown in [Figure 84](#), can be described with the following set of equations:

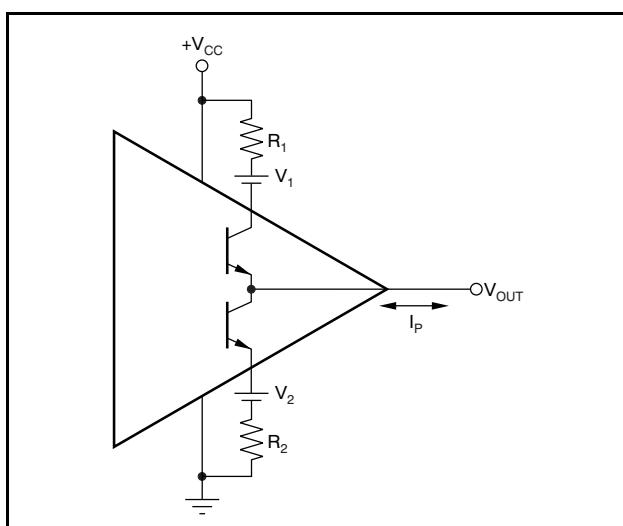
1. As the available output swing:

$$V_{PP} = V_{CC} - (V_1 + V_2) - I_P \times (R_1 + R_2) \quad (10)$$

2. Or as the required supply voltage:

$$V_{CC} = V_{PP} + (V_1 + V_2) + I_P \times (R_1 + R_2) \quad (11)$$

The minimum supply voltage for power and load requirements is given by [Equation 11](#).



**Figure 84. Line Driver Headroom Model**

$V_1$ ,  $V_2$ ,  $R_1$ , and  $R_2$  are given in [Table 2](#) for  $\pm 12V$  operation.

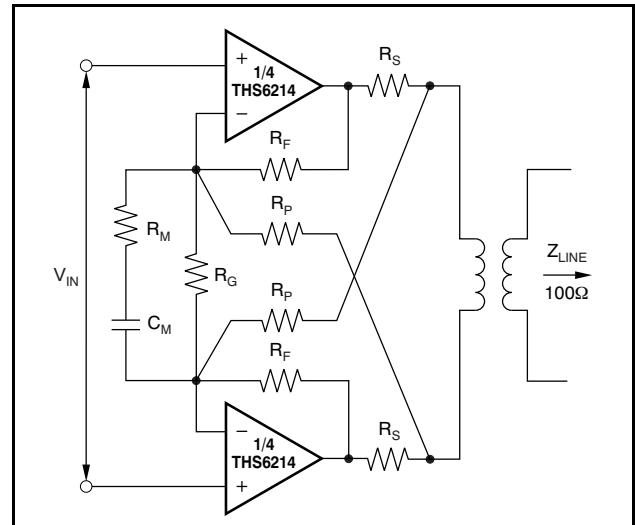
**Table 2. Line Driver Headroom Model Values**

|           | $V_1$ | $R_1$        | $V_2$ | $R_2$        |
|-----------|-------|--------------|-------|--------------|
| $\pm 12V$ | 1V    | 0.6 $\Omega$ | 1V    | 1.2 $\Omega$ |

When using a synthetic output impedance circuit (see [Figure 82](#)), a significant drop is noticed in bandwidth from the specification that appears in the [Electrical Characteristics](#) tables. This apparent drop in bandwidth for the differential signal is a result of the apparent increase in the feedback transimpedance as seen for each amplifier. This feedback transimpedance equation is given below.

$$Z_{FB} = R_F \times \frac{1 + 2 \times \frac{R_S}{R_L} + \frac{R_S}{R_P}}{1 + 2 \times \frac{R_S}{R_L} + \frac{R_S}{R_P} - \frac{R_F}{R_P}} \quad (12)$$

To increase 0.1dB flatness to the frequency of interest, adding a serial RC in parallel with the gain resistor may be needed, as shown in [Figure 85](#).



**Figure 85. +0.1dB Flatness Compensation Circuit**

## TOTAL DRIVER POWER FOR xDSL APPLICATIONS

The total internal power dissipation for the THS6214 in an xDSL line driver application is the sum of the quiescent power and the output stage power. The THS6214 holds a relatively constant quiescent current versus supply voltage—giving a power contribution that is simply the quiescent current times the supply voltage used (the supply voltage is greater than the solution given in [Equation 11](#)). The total output stage power can be computed with reference to [Figure 86](#).

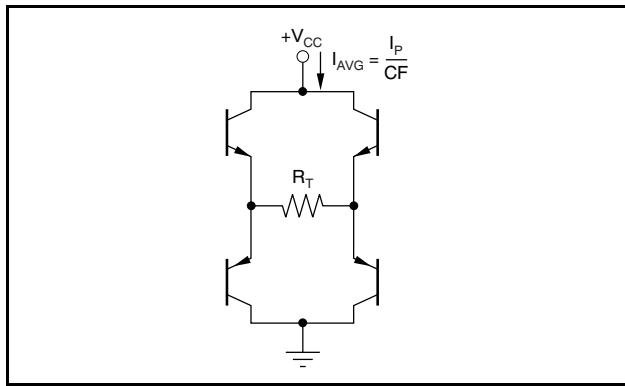


Figure 86. Output Stage Power Model

The two output stages used to drive the load of [Figure 83](#) can be seen as an H-Bridge in [Figure 86](#). The average current drawn from the supply into this H-Bridge and load is the peak current in the load given by [Equation 9](#) divided by the crest factor (CF) for the xDSL modulation. This total power from the supply is then reduced by the power in  $R_T$ , leaving the power dissipated internal to the drivers in the four output stage transistors. That power is simply the target line power used in [Equation 4](#) plus the power lost in the matching elements ( $R_M$ ). In the following examples, a perfect match is targeted giving the same power in the matching elements as in the load. The output stage power is then set by [Equation 13](#).

$$P_{OUT} = \frac{I_P}{CF} \times V_{CC} - 2P_L \quad (13)$$

The total amplifier power is then:

$$P_{TOT} = I_Q \times V_{CC} + \frac{I_P}{CF} \times V_{CC} - 2P_L \quad (14)$$

For the ADSL CO driver design of [Figure 82](#), the peak current is 159mA for a signal that requires a crest factor of 5.6 with a target line power of 20.5dBm into a 100Ω load (115mW).

With a typical quiescent current of 21mA and a nominal supply voltage of  $\pm 12V$ , the total internal power dissipation for the solution of [Figure 82](#) is:

$$P_{TOT} = 21\text{mA} (24V) + \frac{159\text{mA}}{5.6} (24V) - 2(115\text{mW}) = 955\text{mW} \quad (15)$$

## OUTPUT CURRENT AND VOLTAGE

The THS6214 provides output voltage and current capabilities that are unsurpassed in a low-cost, dual monolithic op amp. Under no-load conditions at  $+25^\circ\text{C}$ , the output voltage typically swings closer than 1.1V to either supply rail; tested at  $+25^\circ\text{C}$ , the swing limit is within 1.4V of either rail into a 100Ω differential load. Into a 25Ω load (the minimum tested load), the amplifier delivers more than  $\pm 408\text{mA}$  continuous and greater than  $\pm 1\text{A}$  peak output current.

The specifications described above, though familiar in the industry, consider voltage and current limits separately. In many applications, it is the voltage times current (or V-I product) that is more relevant to circuit operation. Refer to the *Output Voltage and Current Limitations* plot ([Figure 14](#)) in the Typical Characteristics. The X- and Y-axes of this graph show the zero-voltage output current limit and the zero-current output voltage limit, respectively. The four quadrants give a more detailed view of the THS6214 output drive capabilities, noting that the graph is bounded by a safe operating area of 1W maximum internal power dissipation (in this case, for one channel only). Superimposing resistor load lines onto the plot shows that the THS6214 can drive  $\pm 10.9\text{V}$  into 100Ω or  $\pm 10.5\text{V}$  into 50Ω without exceeding the output capabilities or the 1W dissipation limit. A 100Ω load line (the standard test circuit load) shows the full  $\pm 12\text{V}$  output swing capability, as shown in the *Electrical Characteristics* tables. The minimum specified output voltage and current over temperature are set by worst-case simulations at the cold temperature extreme. Only at cold startup do the output current and voltage decrease to the numbers shown in the *Electrical Characteristics* tables. As the output transistors deliver power, the junction temperature increases, decreasing the  $V_{BE}$  (increasing the available output voltage swing), and increasing the current gains (increasing the available output current). In steady-state operation, the available output voltage and current are always greater than that shown in the over-temperature specifications, because the output stage junction temperatures are higher than the minimum specified operating ambient temperature. To maintain maximum output stage linearity, no output short-circuit protection is provided. This absence of short-circuit protection is normally not a problem because most applications include a series-matching resistor at the output that limits the internal power dissipation if the output side of this

resistor is shorted to ground. However, shorting the output pin directly to the adjacent positive power-supply pin (24-pin package), in most cases, destroys the amplifier. If additional short-circuit protection is required, a small series resistor may be included in the supply lines. Under heavy output loads, this additional resistor reduces the available output voltage swing. A  $5\Omega$  series resistor in each power-supply lead limits the internal power dissipation to less than 1W for an output short-circuit, while decreasing the available output voltage swing only 0.5V for up to 100mA desired load currents. Always place the  $0.1\mu\text{F}$  power-supply decoupling capacitors after these supply current limiting resistors, directly on the supply pins.

## DRIVING CAPACITIVE LOADS

One of the most demanding and yet very common load conditions for an op amp is capacitive loading. Often, the capacitive load is the input of an ADC—including additional external capacitance that may be recommended to improve the ADC linearity. A high-speed, high open-loop gain amplifier such as the THS6214 can be very susceptible to decreased stability and closed-loop response peaking when a capacitive load is placed directly on the output pin. When the amplifier open-loop output resistance is considered, this capacitive load introduces an additional pole in the signal path that can decrease the phase margin. Several external solutions to this problem have been suggested.

When the primary considerations are frequency response flatness, pulse response fidelity, and/or distortion, the simplest and most effective solution is to isolate the capacitive load from the feedback loop by inserting a series isolation resistor between the amplifier output and the capacitive load. This series resistor does not eliminate the pole from the loop response, but shifts it and adds a zero at a higher frequency. The additional zero acts to cancel the phase lag from the capacitive load pole, thus increasing the phase margin and improving stability. The **Typical Characteristics** show the recommended  $R_S$  vs Capacitive Load (see [Figure 6](#), [Figure 24](#), [Figure 36](#), [Figure 48](#), [Figure 61](#), and [Figure 73](#)) and the resulting frequency response at the load. Parasitic

capacitive loads greater than  $2\text{pF}$  can begin to degrade device performance. Long printed-circuit board (PCB) traces, unmatched cables, and connections to multiple devices can easily cause this value to be exceeded. Always consider this effect carefully, and add the recommended series resistor as close as possible to the THS6214 output pin (see the [Board Layout Guidelines](#) section).

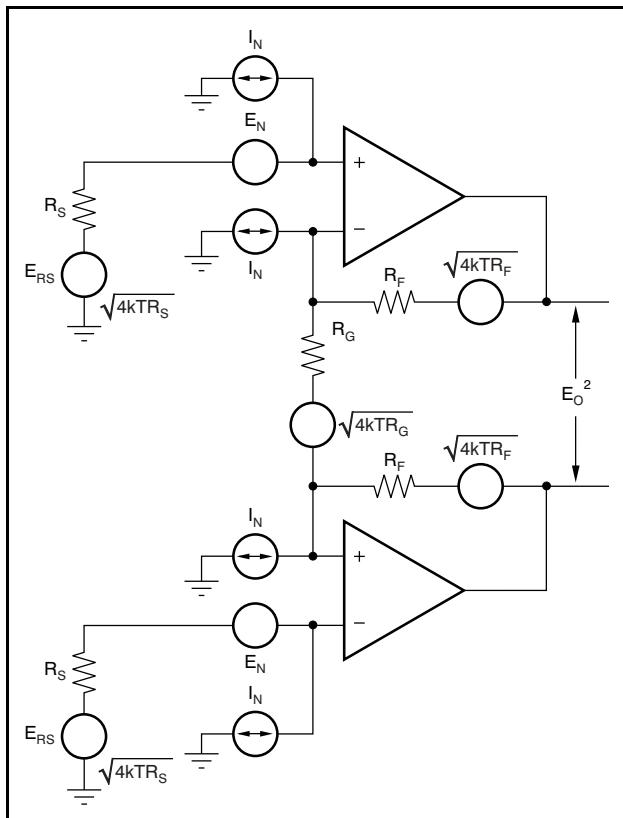
## DISTORTION PERFORMANCE

The THS6214 provides good distortion performance into a  $100\Omega$  load on  $\pm 12\text{V}$  supplies. Relative to alternative solutions, the amplifier provides exceptional performance into lighter loads and/or operation on a dual  $\pm 6\text{V}$  supply. Generally, until the fundamental signal reaches very high frequency or power levels, the second harmonic dominates the distortion with a negligible third-harmonic component. Focusing then on the second harmonic, increasing the load impedance improves distortion directly. Remember that the total load includes the feedback network—in the noninverting configuration (see [Figure 81](#)), this value is the sum of  $R_F + R_G$ , whereas in the inverting configuration it is just  $R_F$ . Also, providing an additional supply decoupling capacitor ( $0.01\mu\text{F}$ ) between the supply pins (for bipolar operation) improves the second-order distortion slightly (from 3dB to 6dB).

In most op amps, increasing the output voltage swing directly increases harmonic distortion. The **Typical Characteristics** show the second harmonic increasing at a little less than the expected 2x rate, whereas the third harmonic increases at a little less than the expected 3x rate. Where the test power doubles, the difference between it and the second harmonic decreases less than the expected 6dB, whereas the difference between it and the third harmonic decreases by less than the expected 12dB. This difference also shows up in the two-tone, third-order intermodulation spurious (IM3) response curves. The third-order spurious levels are extremely low at low-output power levels. The output stage continues to hold them low even as the fundamental power reaches very high levels.

## DIFFERENTIAL NOISE PERFORMANCE

The THS6214 is designed to be used as a differential driver in xDSL applications. Therefore, it is important to analyze the noise in such a configuration. Figure 87 shows the op amp noise model for the differential configuration.



**Figure 87. Differential Op Amp Noise Analysis Model**

As a reminder, the differential gain is expressed as:

$$G_D = 1 + \frac{2 \times R_F}{R_G} \quad (16)$$

The output noise can be expressed as shown below:

$$E_O = \sqrt{2 \times G_D^2 \times \left[ e_N^2 + (i_N \times R_S)^2 + 4kTR_S \right] + 2(i_i R_F)^2 + 2(4kTR_F G_D)} \quad (17)$$

Dividing this expression by the differential noise gain ( $G_D = (1 + 2R_F/R_G)$ ) gives the equivalent input referred spot noise voltage at the noninverting input, as shown in Equation 18.

$$E_O = \sqrt{2 \times \left[ e_N^2 + (i_N \times R_S)^2 + 4kTR_S \right] + 2 \left[ \frac{i_i R_F}{G_D} \right]^2 + 2 \left[ \frac{4kTR_F}{G_D} \right]} \quad (18)$$

Evaluating these equations for the THS6214 ADSL circuit and component values of Figure 82 gives a total output spot noise voltage of  $38.9\text{nV}/\sqrt{\text{Hz}}$  and a total equivalent input spot noise voltage of  $7\text{nV}/\sqrt{\text{Hz}}$ .

In order to minimize the output noise as a result of the noninverting input bias current noise, it is recommended to keep the noninverting source impedance as low as possible.

## DC ACCURACY AND OFFSET CONTROL

A current-feedback op amp such as the THS6214 provides exceptional bandwidth in high gains, giving fast pulse settling but only moderate dc accuracy. The Electrical Characteristics show an input offset voltage comparable to high-speed, voltage-feedback amplifiers; however, the two input bias currents are somewhat higher and are unmatched. While bias current cancellation techniques are very effective with most voltage-feedback op amps, they do not generally reduce the output dc offset for wideband current-feedback op amps. Because the two input bias currents are unrelated in both magnitude and polarity, matching the input source impedance to reduce error contribution to the output is ineffective. Evaluating the configuration of Figure 81, using a worst-case condition at  $+25^\circ\text{C}$  input offset voltage and the two input bias currents, gives a worst-case output offset range equal to:

$$V_{OFF} = \pm(NG \times V_{OS(MAX)}) + (I_{BN} \times R_S/2 \times NG) \pm (I_{BI} \times R_F)$$

where  $NG$  = noninverting signal gain

$$= \pm(10 \times 5\text{mV}) + (3.5\mu\text{A} \times 25\Omega \times 10) \pm (1.24\text{k}\Omega \times 45\mu\text{A}) \\ = \pm50\text{mV} + 0.875\text{mV} \pm 55.8\text{mV}$$

$$V_{OFF} = -104.92\text{mV} \text{ to } +106.67\text{mV}$$

## BOARD LAYOUT GUIDELINES

Achieving optimum performance with a high-frequency amplifier such as the THS6214 requires careful attention to board layout parasitic and external component types. Recommendations that optimize performance include:

**a) Minimize parasitic capacitance** to any ac ground for all of the signal I/O pins. Parasitic capacitance on the output and inverting input pins can cause instability; on the noninverting input, it can react with the source impedance to cause unintentional band limiting. To reduce unwanted capacitance, a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.

**b) Minimize the distance** (less than 0.25in, or 6.35mm) from the power-supply pins to high-frequency 0.1 $\mu$ F decoupling capacitors. At the device pins, the ground and power plane layout should not be in close proximity to the signal I/O pins. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. The power-supply connections should always be decoupled with these capacitors. An optional supply decoupling capacitor across the two power supplies (for bipolar operation) improves second-harmonic distortion performance. Larger (2.2 $\mu$ F to 6.8 $\mu$ F) decoupling capacitors, effective at lower frequencies, should also be used on the main supply pins. These capacitors can be placed somewhat farther from the device and may be shared among several devices in the same area of the PCB.

**c) Careful selection and placement of external components preserve the high-frequency performance of the THS6214.** Resistors should be a very low reactance type. Surface-mount resistors work best and allow a tighter overall layout. Metal film and carbon composition, axially-leaded resistors can also provide good high-frequency performance.

Again, keep leads and PCB trace length as short as possible. Never use wire-wound type resistors in a high-frequency application. Although the output pin and inverting input pin are the most sensitive to parasitic capacitance, always position the feedback and series output resistor, if any, as close as possible to the output pin. Other network components, such as noninverting input termination resistors, should also be placed close to the package. Where double-side component mounting is allowed, place the feedback resistor directly under the package on the other side of the board between the output and inverting input pins. The frequency response is primarily determined by the feedback resistor value as described previously. Increasing the value reduces the bandwidth, whereas decreasing it leads to a more

peaked frequency response. The 1.24k $\Omega$  feedback resistor used in the [Typical Characteristics](#) at a gain of +10V/V on  $\pm$ 12V supplies is a good starting point for design. Note that a 1.5k $\Omega$  feedback resistor, rather than a direct short, is recommended for a unity-gain follower application. A current-feedback op amp requires a feedback resistor to control stability even in the unity-gain follower configuration.

**d) Connections to other wideband devices** on the board may be made with short direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as a lumped capacitive load. Relatively wide traces (50mils to 100mils [.050in to .100in, or 1.27mm to 2.54mm]) should be used, preferably with ground and power planes opened up around them. Estimate the total capacitive load and set  $R_S$  from the plot of *Recommended  $R_S$  vs Capacitive Load* (see [Figure 6](#), [Figure 24](#), [Figure 36](#), [Figure 48](#), [Figure 61](#), and [Figure 73](#)). Low parasitic capacitive loads (less than 5pF) may not need an isolation resistor because the THS6214 is nominally compensated to operate with a 2pF parasitic load. If a long trace is required, and the 6dB signal loss intrinsic to a doubly-terminated transmission line is acceptable, implement a matched-impedance transmission line using microstrip or stripline techniques (consult an ECL design handbook for microstrip and stripline layout techniques). A 50 $\Omega$  environment is not necessary on board; in fact, a higher impedance environment improves distortion (see the distortion versus load plots). With a characteristic board trace impedance defined based on board material and trace dimensions, a matching series resistor into the trace from the output of the THS6214 is used, as well as a terminating shunt resistor at the input of the destination device. Remember also that the terminating impedance is the parallel combination of the shunt resistor and the input impedance of the destination device.

This total effective impedance should be set to match the trace impedance. The high output voltage and current capability of the THS6214 allows multiple destination devices to be handled as separate transmission lines, each with their own series and shunt terminations. If the 6dB attenuation of a doubly-terminated transmission line is unacceptable, a long trace can be series-terminated at the source end only.

Treat the trace as a capacitive load in this case and set the series resistor value as shown in the plot of  *$R_S$  vs Capacitive Load*. However, this configuration does not preserve signal integrity as well as a doubly-terminated line. If the input impedance of the destination device is low, there is some signal attenuation as a result of the voltage divider formed by the series output into the terminating impedance.

**e) Socketing a high-speed part such as the THS6214 is not recommended.** The additional lead length and pin-to-pin capacitance introduced by the socket can create an extremely troublesome parasitic network, which can make it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS6214 directly onto the board.

**f) Use the  $-V_s$  plane to conduct heat out of the QFN-24 and TSSOP-24 PowerPAD packages.** These packages attach the die directly to an exposed thermal pad on the bottom, which should be soldered to the board. This pad must be connected electrically to the same voltage plane as the most negative supply applied to the THS6214 (in Figure 82, this supply is  $-12V$ ).

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)         | Lead/Ball Finish | MSL Peak Temp<br>(3) | Op Temp (°C) | Top-Side Markings<br>(4) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-------------------------|------------------|----------------------|--------------|--------------------------|-------------------------|
| THS6214IPWP      | ACTIVE        | HTSSOP       | PWP                | 24   | 60             | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR  | -40 to 85    | THS6214                  | <a href="#">Samples</a> |
| THS6214IPWPR     | ACTIVE        | HTSSOP       | PWP                | 24   | 2000           | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR  | -40 to 85    | THS6214                  | <a href="#">Samples</a> |
| THS6214IRHFR     | ACTIVE        | VQFN         | RHF                | 24   | 3000           | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR  | -40 to 85    | 6214                     | <a href="#">Samples</a> |
| THS6214IRHFT     | ACTIVE        | VQFN         | RHF                | 24   | 250            | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR  | -40 to 85    | 6214                     | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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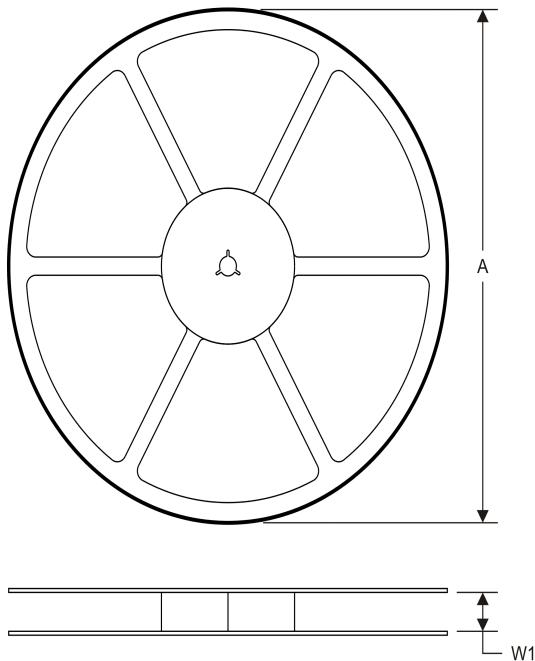
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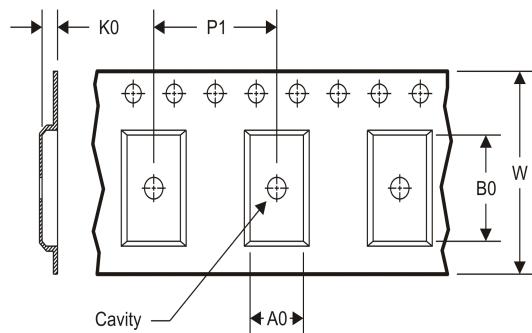
## PACKAGE MATERIALS INFORMATION

### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS



#### TAPE DIMENSIONS



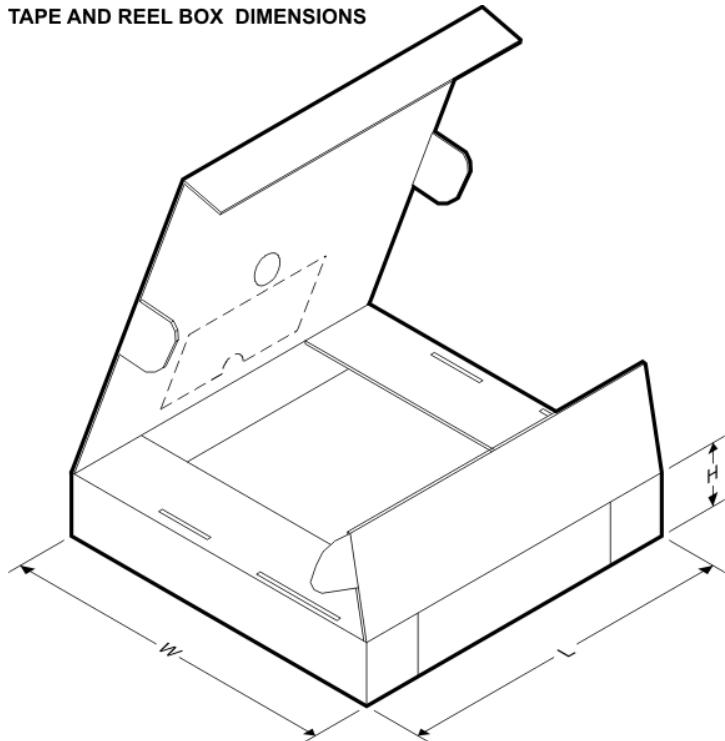
|    |   |
|----|---|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

### TAPE AND REEL INFORMATION

\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| THS6214IPWPR | HTSSOP       | PWP             | 24   | 2000 | 330.0              | 16.4               | 6.95    | 8.3     | 1.6     | 8.0     | 16.0   | Q1            |
| THS6214IRHFR | VQFN         | RHF             | 24   | 3000 | 330.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |
| THS6214IRHFT | VQFN         | RHF             | 24   | 250  | 180.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |

**TAPE AND REEL BOX DIMENSIONS**



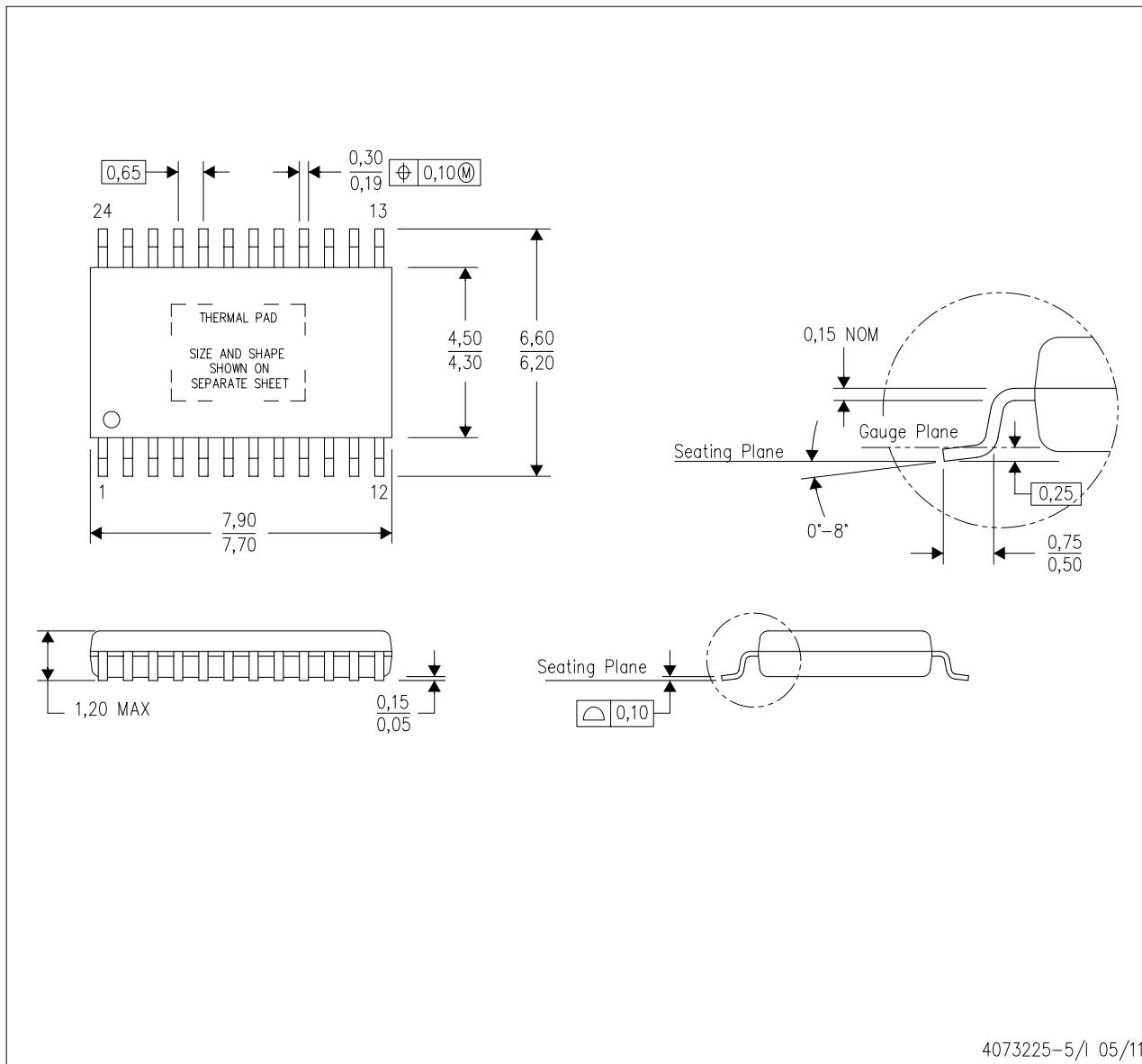
\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| THS6214IPWPR | HTSSOP       | PWP             | 24   | 2000 | 367.0       | 367.0      | 38.0        |
| THS6214IRHFR | VQFN         | RHF             | 24   | 3000 | 367.0       | 367.0      | 35.0        |
| THS6214IRHFT | VQFN         | RHF             | 24   | 250  | 210.0       | 185.0      | 35.0        |

## MECHANICAL DATA

PWP (R-PDSO-G24)

PowerPAD™ PLASTIC SMALL OUTLINE



4073225-5/1 05/11

NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.

## THERMAL PAD MECHANICAL DATA

PWP (R-PDSO-G24)

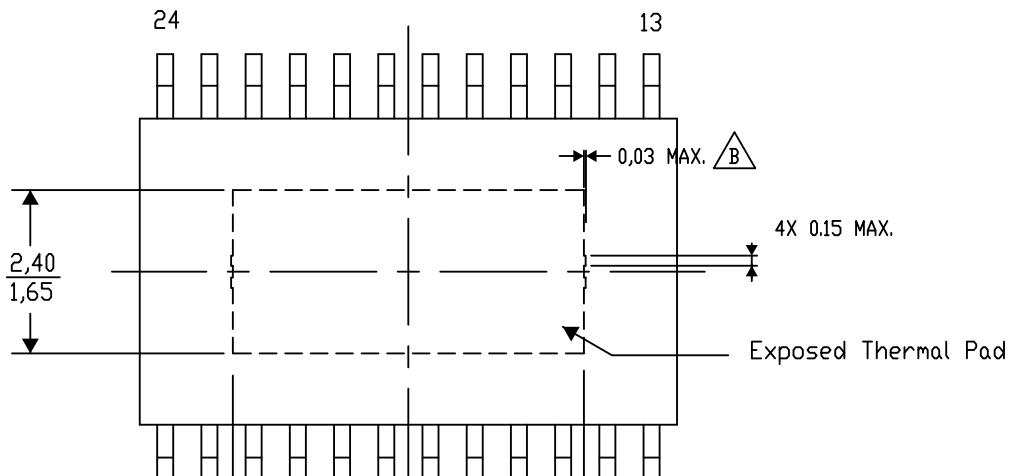
PowerPAD™ SMALL PLASTIC OUTLINE

### THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-29/AO 01/16

NOTE: A. All linear dimensions are in millimeters

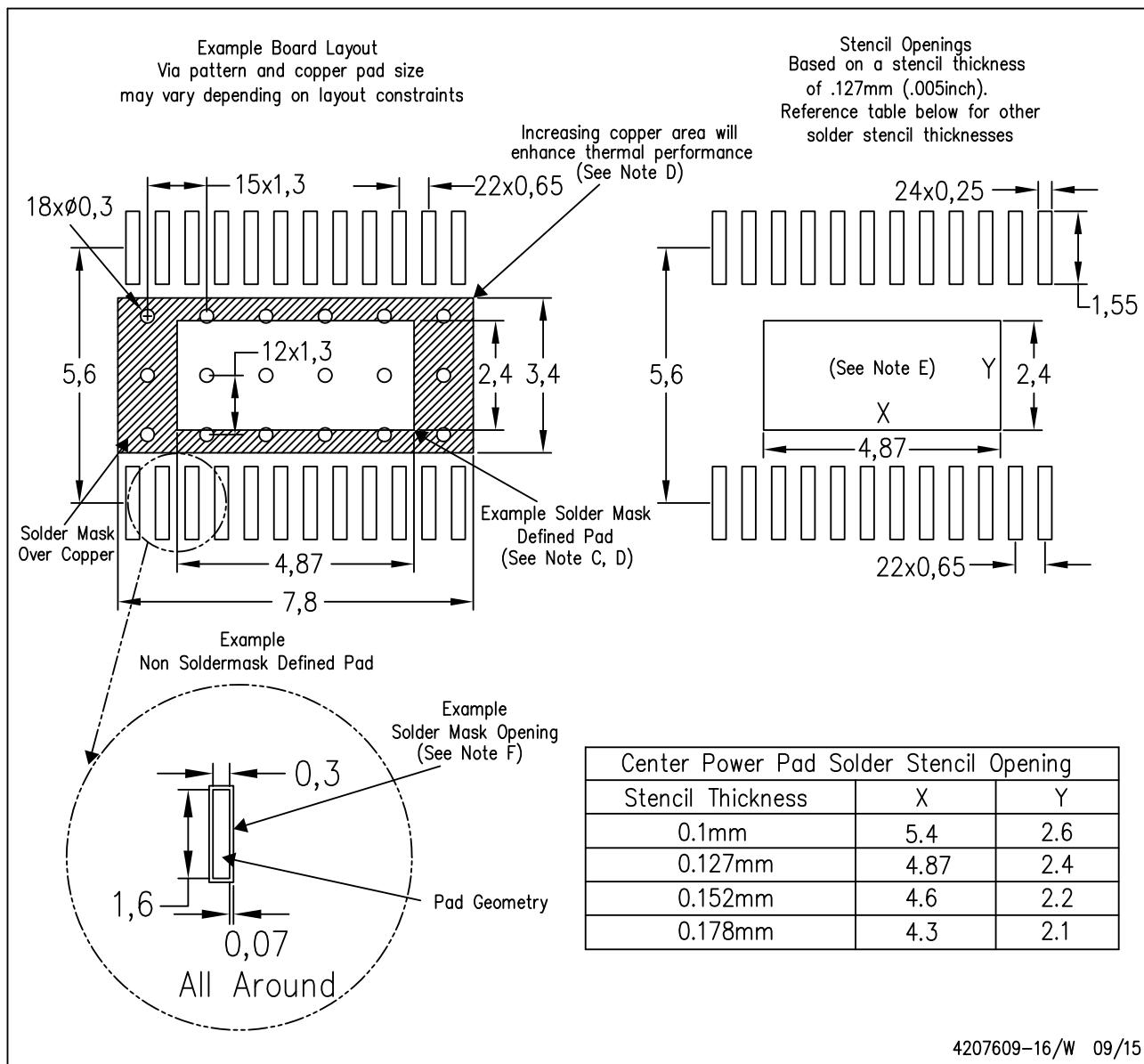
 B. Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments

## LAND PATTERN DATA

### PWP (R-PDSO-G24)

### PowerPAD™ PLASTIC SMALL OUTLINE



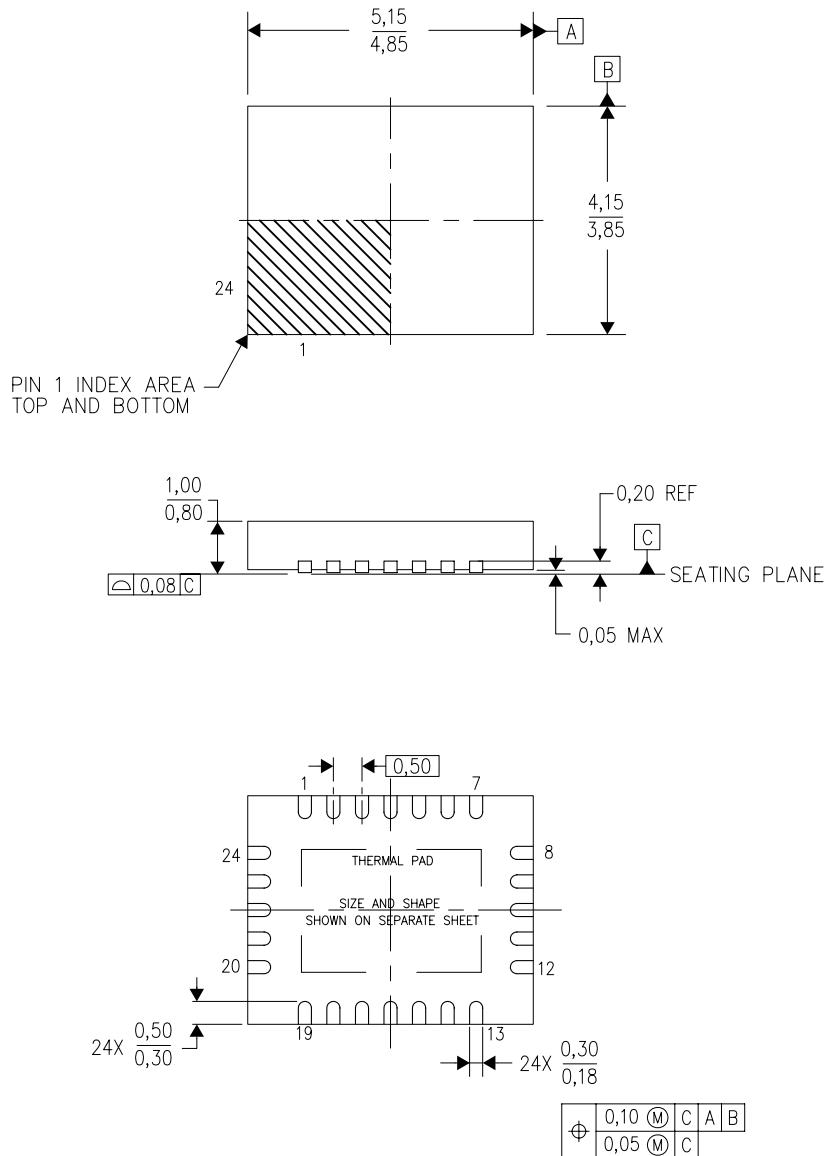
NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
- Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

## MECHANICAL DATA

RHF (R-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



4204845-2/H 06/11

NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) Package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.

## THERMAL PAD MECHANICAL DATA

RHF (R-PVQFN-N24)

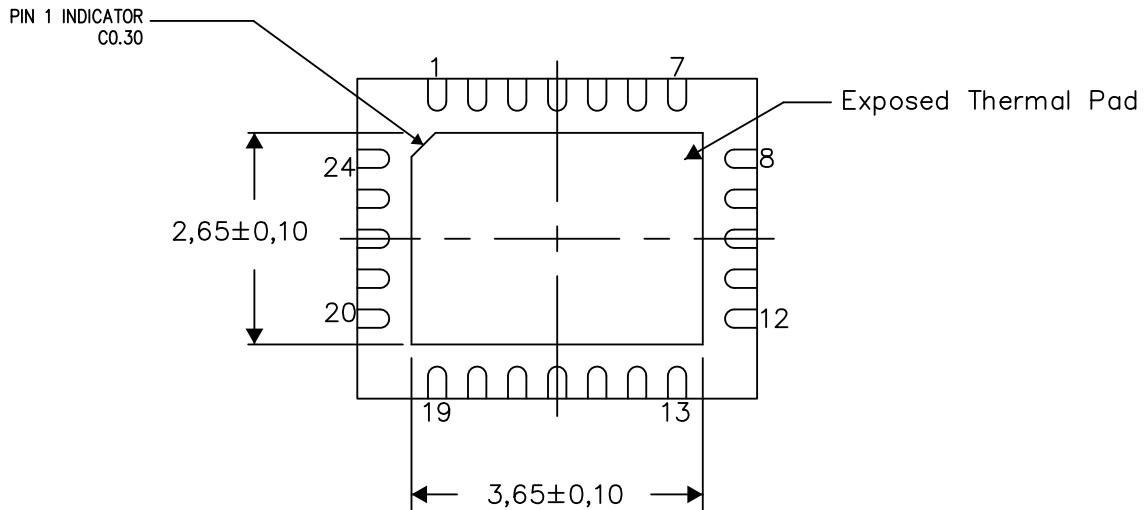
PLASTIC QUAD FLATPACK NO-LEAD

### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

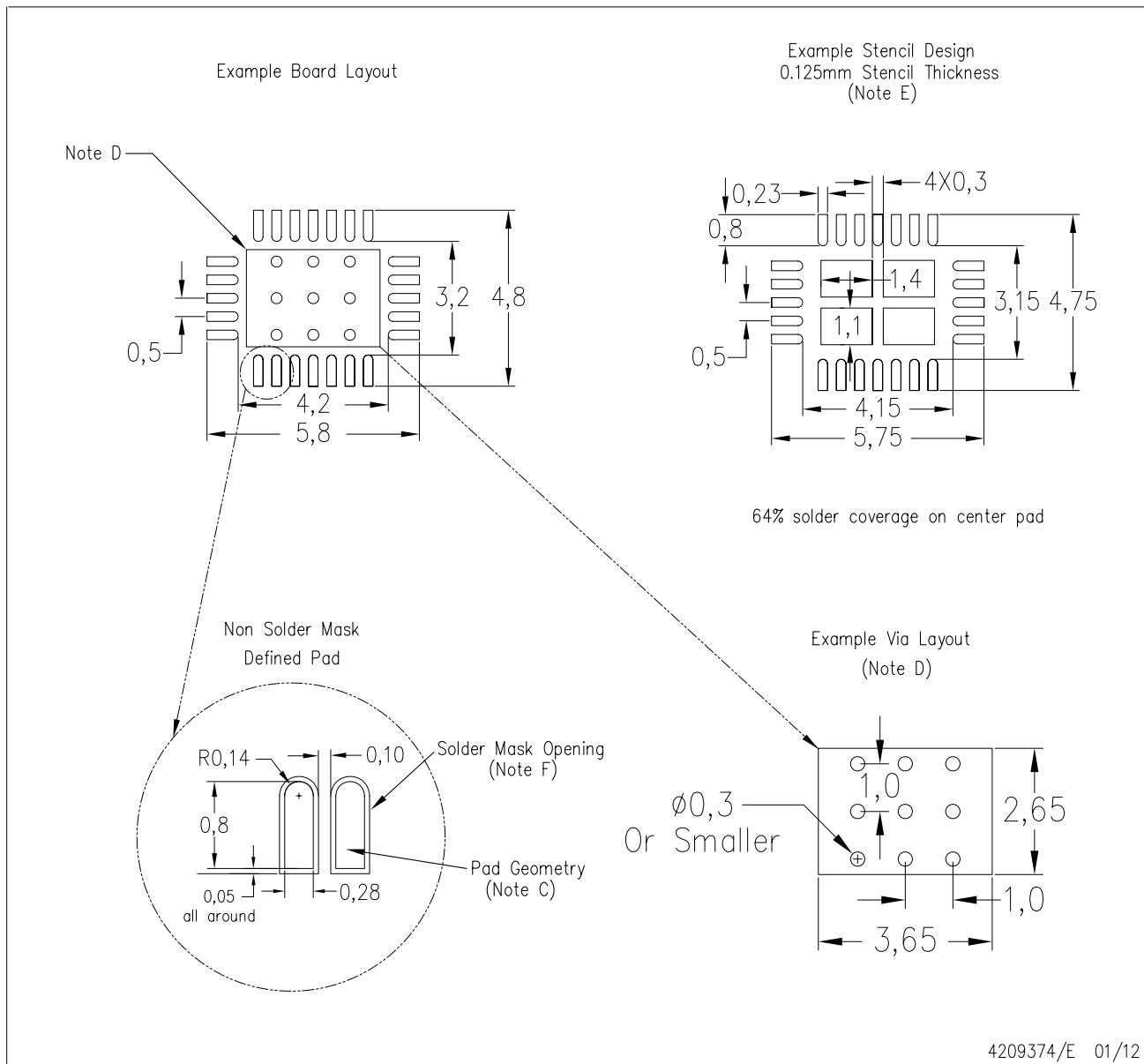
4206360-3/K 02/14

NOTE: All linear dimensions are in millimeters

## LAND PATTERN DATA

RHF (R-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in thermal pad.

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